# DESIGN OF A SECURE ELECTROMAGNETIC BUILDING

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### ABSTRACT

This research explores the design of a secure electromagnetic building, focusing on buildings such as hospitals, embassies, cinemas and prisons. The novelty in this research was the investigation of a surface, which can be embedded into a wall or a window of a room/building, which is "smart". In this case "smart" relates to the surfaces ability to reconfigure itself depending on the environment required for wireless signals that are present in the local surrounding area.

For the purpose of designing a "smart" surface, classical passive Frequency Selective Surface (FSS) designs attenuating more than 60dB being very difficult, due to this poor filtering obtained by current passive FSS designs with limited options to reconfigure it practically.

By introducing tuning elements, such as varactor diodes which are embedded into the FSS structure, vast improvements can be seen which can impair mobile phone signal without the need of greater attenuation levels. The outcome of this is a reconfigurable FSS, where the power transmitted through the FSS is a function of the bias voltage across the diodes. The reconfigurable nature of the FSS allows us to rapidly switch the complex transmission response such that the mobile phone signal passing through the FSS is corrupted. This is the first time that such a system has been tested against the GSM protocol.

Simulations and measurements of the system verified that this concept can achieve the required performance. To test the performance of the new FSS, state of the art signal generators and receivers were employed to evaluate the Bit Error Rate (BER), which is a measure of the quality of a communications signal. BER of greater than 35% were achieved, which is significantly higher than that needed to successfully receive a signal.

Original work has also been carried out investigating the diffraction effects of FSS for secure building applications in order to understand the practical implications of this technology. In summary all aspects of the design of a secure building have been investigated, from the FSS design and the scattering from the room/building which it is intended to be used in.

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### LIST OF PUBLICATIONS

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[3] K.L. Ford, J. Roberts, S. Zhou, G. Fong and J. Rigelsford "Reconfigurable Frequency Selective Surface for use in Secure Electromagnetic Buildings" Electronic Letters,IET, Vol.49 ,No.14, July 2013.

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### LIST OF ACRONYMS

BER	Bit Error Rate
CST	Computer Simulation Technology
CAI	Common Air Interface
CDMA	Code Division Multiple Access
1D	One Dimensional
2D	Two Dimensional
3D	Three Dimensional
E Field	Electric Field
FIT	Finite Integration Technique
FSS	Frequency Selective Surface
FDTD	Finite-Difference Time-domain
2G	Second-Generation
3G	Three-Generation
GSM	Global System for Mobile Communication
MLSE	Maximum Likelihood Sequence Estimator
NLOS	Non Line of Sight
PEC	Perfect Electric Conductor
PN	Pseudo Noise
PSS	Phase-Switch Screen
RCS	Radar Cross Section
RAM	Radar-Absorbent Material
S Parameter	Scattering Parameter

TE	Transverse Electric
ТМ	Transverse Magnetic
TEM	Transverse Electromagnetic
TETRA	Terrestrial Trunked Radio
UMTS	Universal Mobile Telecommunications Service
UWB	Ultra Wideband
WLAN	Wireless Local Area Network

# LIST OF SYMBOLS

F	Frequency (Hz)
Т	Time (s)
W/C	The Mass Ratio of Water to Cement
Z <sub>0</sub>	Free Space Impedance $(377\Omega)$
ε	Electric Permittivity
λ	Wave Length
c	Speed of Light in Vacuum

### CHAPTER 1 INTRODUCTION

#### 1.1 Background

The mobile telecommunication industry is undergoing an increasing rate of market growth, combined with the advancement of technological change[1]. In the early stages, mobile services only saw small numbers of subscribers, but now many mobile phone users in the UK have more than one phone. This means mobile phones are heavily used in the UK, which will cause problems in locations where they need to be prohibited, such as prisons, theatres, hospitals, embassies and so on. For example, in a prison, a prisoner might smuggle a phone to do criminal activities including arranging a jailbreak, threaten someone or supply drugs to other prisoners. If mobile phones are used in hospitals they may interference with medical equipment which is stated in NHS website [2], such as pacemakers, electronic monitoring devices, pumps etc. In cinemas or theatres, silent environments are required, these are just a handful of applications, where the location requires a method to block the transmitted phone signals and novel solutions need to be obtained.

The restriction of devices is still quite difficult to enforce, with many mobile phones still being brought inside restricted areas. Therefore, alternative methods need to be explored preventing the usage of these devices inside a building. Current research and development into this field has developed at a rapid pace, exploring different methods, e.g. mobile phone jammers, RF signal shielding materials or a Frequency Selective Surface (FSS).

Some European countries allow the use of mobile phone jamming in certain public places, e.g. France has decided to jam phone signals in cinemas to allow audiences to enjoy films without interruption. Many countries actually prohibit the use of jammers, like in the UK where mobile phone jammers are illegal according to the Wireless Telegraph Act 1949 [3].

RF signal shielding materials attenuate signals up to 90dB over a spectrum ranging from 50MHz to over 20GHz. This is a lightweight and easy method for isolating RF signals [4]. However this would block all signals, including emergency service.

Frequency Selective Surfaces (FSS) have been researched for many years for their ever increasing use in antennas and Radar Cross Section (RCS) reduction applications [5].

Recently theoretical and experimental work have demonstrated that a FSS could be applied to a building, changing the propagation for different frequencies (GSM, UMTS, Bluetooth and WLAN) which could be controlled to affect its surrounding environments [6]. The advantage of this solution is that a chosen frequency range can be selected to be blocked, so that not all wireless signals are lost within entering the building.

#### **1.2 Motivation and Objectives**

This research focuses on the use of FSS to design a secure electromagnetic building, where there is a need to control a mobile phone's signal in/out of the building. An example of a prison is given in this research, with prison operators searching for different ways of preventing prisoners covertly using smuggled mobile phones in their cells. The issues they face are that they also need to allow emergency service frequencies to enter the building so they can still communicate freely using internal radio systems. Various possible FSS solutions have been designed to potentially meet this requirement [7, 8].

In order to design a FSS for this building application, the power levels need to be assessed inside the building to make sure it can meet the 'secure' requirement. This would be worked out using various modelling techniques and measurement campaigns which will be discussed in 0 and Chapter 7. When very high attenuation levels are required for the FSS design, Non-specular scattering will become important for Non Line Of Site (NLOS) transmission where diffraction can be significant, and which also needs to be assessed.

To evaluate the influence of diffraction scattering from the edge of an FSS panel on the window aperture, an understanding is required of how the FSS performs in high signal strength areas. Using geographical locations, 2G cellular network signal quality was assessed for all UK prisons, using data provided by the network operators. This information is only indicative and does not provide values of actual signal strength but rather gives an approximation to the level of service in areas that we may wish to remain secure. During the analysis a total of 249 prisons were assessed across the UK. These prisons can be categorised into five different types as shown in Table 1-1: category M, A, B, C, and D, where category A has the highest security and category D has the least.

М	Maximum security: paradoxically these can be B as well as A. Specialist attention is paid here, and they are not many in number.
Α	Closed prison: prisoners are those whose escape would be highly dangerous to the public or national security. A type prisons are designed to make escape impossible.
В	Closed prison: prisoners are those whose do not require maximum security, but for whom escape needs to be made very difficult.
С	Closed prison: prisoners cannot be trusted in open conditions but are considered to be prisoners who are unlikely to make a determined escape attempt.
D	Open Prison, prisoners can be trusted in open conditions.

Table 1-1: The categories of prison [9]

All UK prisons from the extracted prison list have been categorized into their security level type and the associated claimed by the signal strengths for known mobile operators (Appendix I). Table 1-2 contains example of category A prison.

Prison Name	Address	Post Code	Category	OP-A	OP-B	OP-C	OP-D
HMP MANCHESTER	Southall Street, Strangeways, MANCHESTER	M60 9AH	А	5	5	2	5
HMP ALTCOURSE	Higher Lane, Fazakerley, LIVERPOOL	L9 7LH	А	5	5	2	5
HMP/YOI DONCASTER	Off North Bridge, Marshgate, DONCASTER, South Yorkshire	DN5 8UX	А	5	5	2	5
HMP BOWHOUSE	Mauchline Road, Bowhouse, KILMARNOCK, East Ayrshire	KA1 5AA	А	5	3	1	5
HMP & IDC MAGHABERRY	17, Old Road, Upper Ballinderry, LISBURN, Co.Antrim	BT28 2PT	А	5	4	2	5

Table 1-2: The Category A Prison List

Table 1-2 shows the first few rows of category A prisons outlining the signal strength rating on a scale of 1-5 where 1 is weakest for each mobile phone provider in that area by postcode. Graphs to compare these results are then generated to analyse the signal strength across different categories as shown in Figure 1-1.

Figure 1-1 to Figure 1-5 shows the percentage of prisons grouped by their expected received signal quality in a given prison category. OP-A to OP-D are network operators.



Figure 1-1: Signal Quality for Category M



Figure 1-2: Signal Quality for Category A



Figure 1-3: Signal Quality for Category B



Figure 1-4: Signal Quality for Category C



Figure 1-5: Signal Quality for Category D

The results shown in Figure 1-1 to Figure 1-5 illustrate the potential problem that is faced when designing a secure building, where the indicated signal levels can be very high and may require a high level of attenuation from an FSS solution. In such a situation, non-specular scattering could also provide a viable communication channel independent of the specular FSS performance.

In order to understand the FSS attenuation which may be required in a high signal area, several reference measurements were conducted both outside and inside the Sir Frederick Mappin Building at the University of Sheffield.

This location was selected due to it being in an area of excellent signal strength for all network operators so obtaining a good benchmark. Figure 1-6 shows an illustration of the building tested, highlighting the locations which were measured.



Figure 1-6: Front and Top view of Mappin Building

To perform the measurements, the three monopole antennas shown in Figure 1-7 were manufactured to operate at 400MHz, 900MHz and 1800MHz, with their lengths being 187.5mm, 83.3mm and 41mm respectively. The antennas were connected to a portable spectrum analyser (Rohde & Schwarz FSH3), which can operate over a frequency range of 100kHz to 3GHz with a resolution bandwidth being from 100Hz to 1MHz. The power measurement capability on this device is from -125dBm to +2 dBm.



Figure 1-7: Monopole antennas

At each location, power measurements were carried out over the full TETRA band and the GSM 900/1800 downlink frequency bands (935MHz - 960MHz and 1805–1880 MHz). The measurements were carried out during dry conditions, with an external temperature of approximately 6 C. Three samples were taken for each location, with a summary of the results being shown in Table 1-3.

	Power (dBm)			
Location	400MHz	900MHz	1800MHz	
Left Corner of MB	-57	-62	-56	
E132	-55	-52	-65	
F151	-46	-61	-62	
Outside of Cafe	-57	-60	-45	
Inside of Cafe	-63	-69	-48	
LT1	-61	-62	-54	
F162	-55	-64	-60	
<b>Right Corner of MB</b>	-55	-53	-51	
E150c	-62	-44	-55	
E150d	-59	-49	-61	
F166	-56	-51	-57	

Table 1-3: Measured Signal Strengths at Various Locations

Table 1-3 denotes bold for outdoor locations with Figure 1-8 showing the locations of the base station antennas in relation to the building. Throughout this area, the signal strength is classified by all mobile operators as being of excellent signal quality. The maximum power for the TETRA band is -46dBm, with a variation of 17dB. The maximum power for the GSM900 band is -44dBm, with a variation of 25dB. The maximum power for the GSM1800 band is -45dBm with a variation of 20dB.



Figure 1-8: Marked Locations of Mobile Base Stations

From the measurements taken and analysed, it is possible that a secure room would require above 60dB of attenuation to successfully stop a wireless communication channel. Due to this reason, these research objectives are set as follows:

- Non-specular scattering from a FSS need to be analysed in more detail.
- Different methods need to be investigated to reduce non-specular scattering.
- Due to the use of passive FSS designs attenuating more than 60dB being very difficult to design in practice, a reconfigurable switching FSS to be designed and measured to corrupt a received mobile phone signal inside a building by change the complex transmission response, causing the receiver inside a building being unable to determine the data which was transmitted from outside the building.

#### **1.3** Summary of the Work Presented in this Thesis

The areas of this thesis are sectioned into nine chapters:

The first chapter is an introduction of research, introducing the project background and objectives.

The second chapter explains FSS theory, showing different types of FSS and how FSS interact with building structures. It also outlines the need for privacy within a building structure as well as brief look into several digital modulation schemes used for RF carriers.

The third chapter provides simple FSS simulation results to familiarize the use of the CST simulation environment by designing a simple prison cell structure which is later used in subsequent chapters.

The forth chapter covers the development of numerical modelling, outlining the model of the GSM system which would be built using MATLAB. This chapter explains details for how each module element works in a GSM system, as well as introducing CST as a software environment being used for the simulation in the following chapter.

The fifth chapter shows the design of a reconfigurable frequency selective surface that can be utilised to corrupt a mobile phone signal over the channel. This is achieved by making the receiver being unable to determine the sent data which is transmitted by the base station. This chapter will also show the simulation results of a 2-D BER surface plot comparing against the phase shifts and switching frequencies.

The sixth chapter contains the measurement set up and results for a single polarization and dual polarization reconfigurable switching FSS.

The seventh chapter presents research into diffraction from a FSS in the application of a secure building, to prevent a signal from entering or leaking from a room. Non-specular scattering will be of importance for Non Line of Site when very high attenuation levels are required. For this reason, the levels of diffraction scattering from a FSS need to be investigated to meet the attenuation needed by the FSS solution.

The eighth chapter is a conclusion, summarising the research finding, including a discussion of the research contributions and illustrating the research limitations.

The ninth chapter briefly outlines further possible research developments that may be expanded upon from this research area.

The contribution of this work is:

- Introducing a reconfigurable switching FSS can impair a GSM signal without the need of greater attenuation levels.
- 2D surface plots and measurement results of the reconfigurable switching FSS presented, showing a BER of over 30% for a wide range of input parameters.
- Illustrates the importance of FSS diffraction for secure building applications in high signal strength areas.
- Three methods for reducing the non-specular scattering mechanism being introduced.

### **CHAPTER 2 LITERATURE REVIEW**

This section reviews theory behind the basics of an FSS model, in order to understand their equivalent circuit and their transmission response. After this, research into different types of FSS which could be utilised on a buildings structure such as active or transparent FSS. The convoluted FSS also has been looked into to reduce FSS unit cell size.

Previous work from other researchers are also investigated to see how the uses of a FSS are used to control the propagation in/out of a building at different frequencies which includes the consideration of signal propagation within a building which is influenced by specific features. Following that, a more feasible reconfigurable switching FSS would be reviewed. Finally, different digital modulation schemes has been introduced.

#### 2.1 The need for Privacy

The demand of utilising radio spectrum is increased rapidly causing degrade wireless communication with channel congestion within indoor environments, especially unlicensed bands, were users privacy could be effected by nearby receivers eavesdropping on their conversation illegally [10]. FSS can be used as an isolator in an indoor environment by providing band selective screening which can selectively reject unwanted frequency range within buildings to reduce interference between adjacent co-channel and reject interfering signal from surrounding building [11].

FSS could improve frequency reuse in building which can lead to increase of network capacity, where incorporating FSS would control the Electromagnetic Architecture of Buildings (EAoB) [12]. According to inverse square law approximation, it recommends just 10 dB reduction decreases cell size required for frequency reuse by a factor of 3, and reuse becomes feasible within buildings and the efficiency of use of the radio spectrum would be potential by enhanced [13].

#### 2.2 FSS Theory

Frequency Selective Surfaces (FSS) have been researched for many years for their ever increasing use in reflector antennas and Radar Cross Section (RCS) reduction applications[5]. Historically, it can be traced back as far as the 18th century, were the American physicist David Rittenhouse discovered light spectrum from a street lamp can be filtered through a silk handkerchief [14]. This became the frequency selective property used for this FSS application. One of the earliest patents was granted in 1919 as shown in Figure 2-1, in which an array of elements of finite length  $2\ell$  which should be preferably  $\lambda/2$ , but may be made shorter or longer by inserting in it either a condenser or an inductance with the same spacing  $D_x$ . This periodic surface structure has been intensely studied since the mid-1960s due its large interest in military applications [15].



Figure 2-1: Periodic Surface of Elements of Length 2ℓ

[15]

Before starting analysis of a FSS structure, the relevant concepts in electromagnetic theory has been reviewed to understand how a FSS can perform as a filter.



Figure 2-2: Plane Wave Incident FSS and the Electrons Effect [16]

In Figure 2-2 (a), the excitation signal incident to the FSS from left is propagating at a normal incidence angle. The black spot represent a single electron, with the FSS being orthogonal to the incident wave propagation direction. The E-Vector of the incident wave is located on the FSS which bring a force to bear on the electron, causing it to oscillate. A portion of the energy from the incident signal will be absorbed by the oscillating electrons, causing the energy to be converted into kinetic energy [16]. After the electrons absorbed the energy, the electrons start to oscillate, which behave like an electric dipole, with their radiation patterns being emitted on both sides of the FSS. The radiation emitted on the right hand side of the surface will interfere with the incident wave, causing their E-fields to cancel each other out. The left hand side of the radiation is the reflected wave [16].

In the Figure 2-2 (b), the FSS element which is orthogonal to the E-Vector of the incident wave. If the electron is restrained to only go along this wire, the energy from the incident wave will not be absorbed by electron due to it being orthogonal to the direction in which the electron is oscillating. Therefore the incident wave wouldn't be affected by the electron and causing the wave to be transmitted through the surface. A incident wave transmission therefore depends on the pattern of a surface, which will decide the FSS behaviour [16].

A regular FSS is a flat two dimensional planer periodic resonant structure consisting of one or more metallic designs, which are backed by a dielectric substrate in Figure 2-3. These structures are usually arranged periodically [17]. The FSS behaves as a passive electromagnetic filter, which may have a low-pass, band-pass, band-stop or high-pass property[18], attenuating or reflecting a selected frequency band. An elements 'shape and size' can affect the response of the FSS as well as its 'angle of incidence', 'polarisation', 'permittivity' and 'thickness of the substrate' [19].



Figure 2-3: Frequency Selective Surface

A FSS behaves as a spatial filter, with an equivalent LC circuit being used to represent its overall response characteristics. A band stop filter and a band pass filter are used as an example in Figure 2-4, which is to show their equivalent circuits and transmission response.



Figure 2-4: FSS with their Equivalent Circuit and Transmission Response

The advantage of these two models is that the transmittance propagating pass the filter is independent of the sources polarization due to the filters being symmetrical under rotation. If for example the FSS is rotated 90°, both components of polarization would "see" the same grid geometry [16].

To extend the FSS functions, additional electronic devices were embedded into classical periodic FSS structure to create active grid arrays [18]. Lee and Fong in their paper in 1971 mentioned an active corrugated structure that can control the phase of the reflected wave but also its magnitude of the reflection coefficient which has potential applications, e.g. in phase array radar and microwave amplification [21].

Recently theoretical and experimental work have demonstrated that FSS could be applied to a building, changing the propagation for different frequencies (GSM, UMTS, Bluetooth and WLAN) which could be controlled to effect its surrounding environments [6].

#### 2.3 Types of FSS

In this section three types of FSS are introduced which could be used on a building structure, attempting to secure it over different unwanted frequency bands.

#### 2.3.1 Reconfigurable Switching FSS

Reconfigurable active FSS are widely used in current communication systems for a FSS design which can provide a better reconfigurable solution for a given building architecture. It adds additional bias circuitry to the traditional passive FSS which can vary the frequency response with time to change its characteristics [22]. These active FSS are designed with varactor diodes that can be adjusted by altering the DC voltage across the varactor diodes connections to directly control the reflection and transmission response of the active tuned FSS [23]-[24].

Switching FSS can also be used to switch between reflective and transparent states for a building application, which is to switch the EM coupling between individual rooms inside a building or to an external environment [25]. Figure 2-5 is an example for a switching FSS which has been fabricated using a square loop FSS design with each unit cell having four PIN diodes placed symmetrically [26].



Figure 2-5: Front Close-Up View of a Switchable FSS Prototype [26]

Reconfigurable switching FSS using a spread spectrum system can be traced back to 1984, with a patent paper mentioning it as a 'covert communication system' which employs an extensive bandwidth to improve its signal to noise ratio [27]. "The term "covert communication system" means a communication system that prevents unauthorized detection of the communication traffic". It includes four arrangements: first, translate bit '1' and '0' into PN (Pseudo Noise) code sequence which spread over a large bandwidth. Second, the PN sequence has been transmitted at a low power level environmental noise of propagation medium. Third, received the PN sequence [27].

Recently, this technology has been used in a Phase-Switch Screen (PSS) as well. Chambers and Tennant explored a lot of research in this area [28-35], with a PSS being a device that can reduce a target's Radar-Cross Section (RCS) by reflections and redistributing electromagnetic energy of the incident signal outside the bandwidth of the detection systems so that only a proportion of energy can be received [32]; Figure 2-6 illustrates an example for the signal incident for a PSS. The grey coloured trace represent the PSS screen ON which the scattered signal from the unmodulated PSS shows a classic  $\sin x/x$  response centred on the 11GHz carrier. The black coloured trace represents the PSS screen OFF which the modulated FSS shows the energy of the response has been redistributed into sidebands at every 20MHz [35]. This functionality is very useful for military applications which ultimately aims to make and object undetectable on radar.



Figure 2-6: Frequency Spectrum of Reflected Signal from PSS [35]

PSS has different designs: single-layer, dual-layer and dual-polarised. To understand the structure, the simplest single-layer planar PSS will be used as an example in Figure 2-7. It has a switchable active front layer and a PEC backplane, the impedance states of the active layer can be switched very rapidly from high to low. When  $R = \infty \Omega$ , the layer is switched off, it can be switched to totally transparent states to the incident signal, when  $R = 0\Omega$ , the layer is switch on, with the incident signal being reflected back [36]. If the illuminating signal is a unit amplitude normalised plane wave with an angular frequency of  $\omega$ , the reflected signal back can be expressed as  $\cos(\omega t)$  when the active screen is ON and  $\cos(\omega t + 2\beta d)$  when the active screen is OFF, where  $\beta = 2\pi/\lambda$  and  $\lambda = C/f$ . The term  $2\beta d$  describes the phase shift between the two reflected waves from the front active layer and PEC backplane, when the distance *d* between these two layers equal to  $\lambda/4$ , the phase difference is 180°. So if the active layer is switched between ON and OFF states for a response to a modulating function being applied, a phase modulated reflected signal would be produced [37].



Figure 2-7: A Single-layer Planer PSS [35]

#### 2.3.2 The Transparent Frequency Selective Surface

When rooms need to be screened to stop a signal in or out the windows also need to be shielded. This requires the FSS to be optically transparent to let light through with the following research on transparent FSS being carried out.

Parker et al. [38] first investigated FSS structures that used optically transparent conductive elements. In his work, circular patch (band-stop FSS) and slot ring (band-pass FSS) patterns were employed as shown in Figure 2-8. A square lattice structure of elements is arranged, fabricated using a resistance sheet of 4-8 ohm-sq thin-film silver, bonded onto a thin film of polyester [38].



Figure 2-8: Circular Patch (a) and Slot Rings (b) In a Square Lattice Arrangement [39]

FSS glass has also been developed, being an Electro-magnetic wave reflector, containing a collection of thin antennas manufactured onto it. Silver (95% Ag) was chosen as the element material that can be deposited directly on glass. Two band- stop FSS structures are employed for this application. Both being of a Y type antenna design, the first is illustrated in Figure 2-9(a) which is designed to be an FSS element having an attenuation peak at 1.9GHz. The second illustrated in Figure 2-9(b) adds the added ability of shielding for two different bands at the same time with its attenuation stretching to being more than 40dB at 1.9GHz and 2.4 GHz. Measurements concluded a 0.5mm diameter silver antenna and prove it had satisfactory performance [40].



Figure 2-9: (a) 1.9GHz Single Shield Type (b) 1.9GHz, 2.4GHz Dual Shield Type [39]

#### 2.3.3 Convoluted Frequency Selective Structures

In the process of designing a FSS which operates below the frequency range of 3GHz, the size of a unit cell can become quite large depending on the range of frequencies of interested [41]. Using a larger conducting screen, a finite smaller sized FSS panel could be placed within a cut aperture, if a larger panel is required using a reduced sized FSS to save on manufacturing costs. One of the benefits of using an element which is reduced in size is an enhanced stability in the transmission or reflection frequency response when different angles of incidence from the exciting wave [7]. Therefore convoluted FSS designs can be used to produce resonating structures with a smaller unit cell dimension, which improves the angular stability of the frequency responses of the surface [42].

A FSS panel that can be used on the window of each prison cell that can be designed to block signals between base stations and mobile phones (Appendix II). A key requirement of the FSS panel needs to be the continuity of optical field through the FSS, so the choice of material for the substrate is glass ( $\varepsilon_r = 7.5$ ,  $tan\delta = 0.02$ ). In the paper [43], two single layer FSS with modified multiple-loop elements are printed on the top and bottom of a glass panes, which is a pair of glass panes each 5mm thick with a 6mm air gap between them in Figure 2-10. This design also can reduce heat emission and to block noise in the building. When a triple-band FSS with three independent band-stop responses are needed, the single-band single-layer FSS must be placed in such a way that three resonant structures reside on the same surface. This is the reason why three loops are printed on each both of the glass substrate.

The design operates at three bands for (890MHz - 960MHz, 1710MHz - 1875MHz and 1920MHz - 2170 MHz), rejecting all three mobile bands at over -30dB attenuation.



a=18.82mm	b=21.96mm	c=32mm	d <sub>1</sub> =4.43mm	d <sub>2</sub> =2.82mm
g=1mm	k <sub>1</sub> =0.55mm	k <sub>2</sub> =0.61mm	k <sub>3</sub> =0.94mm	l <sub>1</sub> =4.71mm
l <sub>2</sub> =8mm	m <sub>1</sub> =0.96mm	m <sub>2</sub> =1.26mm	h <sub>1</sub> =6mm	h <sub>2</sub> =5mm

Figure 2-10: Structure of the Convoluted Transparent FSS Structure [43]

#### 2.4 Use of FSS on Building Structures

This area concentrates on large scale simulation methods both experimental and development validation, assessing characteristics of electromagnetic fields due to radio transmissions in large cavities, using building based case studies.

From the papers which have been studied, they typically build very simple cavities as a building model, which only have basic walls, doors and windows. The propagation within

each building are influenced strongly by the layout of the building creating specific feature points [44], the construction materials [45], and the building type i.e. Flat, Office Building, House, etc. To summarise this work, they can categorised into several areas:

Transformation of building walls making them into a frequency selective surface, which not only filters out unwanted interference or radio frequencies, but also allows desired radio spectrum to pass through. Additionally, the frequency selectivity is closely related to the incident angle and dielectric properties of the buildings material [46].

For accurate propagation channel modelling, knowledge of reflective properties of building materials is required for future pico-cellular indoor THz communication systems [47]. The THz time-domain spectroscopy is used to measure reflection coefficient and calculating the reflection coefficients using Fresnel's equations. Also the roughness of a surface has an impact on attenuation of the reflection depending on the location from the transmitter as opposed to a smooth surface [47].

In construction of large buildings, rebar is commonly used to reinforce concrete. Over a frequency range of 100-6000MHz, transmission and electronic magnetic reflection coefficients are calculated for a reinforced concrete walls as a function of rebar geometry and wall thickness using finite-difference time-domain techniques [48]. The methods used to reinforce concrete walls depend on the structural requirements of the building, with three general rebar configurations being analysed [48]. By changing the rebar lattice period, wall thickness, rebar diameter or the rebar geometry, its electrical properties change, causing the transmission coefficient and reflection coefficient to change. Concrete and rebar separated have their own very different properties when subject to radio frequencies, but these effects change completely when integrated together making it more difficult to model [48].

Using the FDTD method, a 2D model of a nearby building has been analysed; with the results indicating that a reflection from the nearby buildings can increase the received power on lower floors [49]. Adjacent floors in a multi-storey building are dominated by power penetrating though the floors and reflection by close by building. Assuming isotropic spreading in the third dimension, this 2D simulation can be extended to 2.5D [49].

There are different ways in which to make a material act as a wave absorber:

- Magnetic wood made of the wood and magnetic powder which can be easily processed due to characteristics similar to other woods and has a texture just like wood, it can absorb electromagnetic wave[50].
- Three-layer wave absorber which is made of common building materials; an advantage of this is that it can save costs and easy to construct [51].

Research has shown the penetration loss and time dispersion on building materials for UWB (Ultra Wideband) ranging over a spectrum of 3.1GHz to 10.6GHz; where dry wood, partition board, gypsum and glass are considered as obstruction materials. The higher the material thickness becomes causes more penetration loss, so the UWB receiver design needs adapted to achieve the high accuracy of the performance on the receiver when using such materials [52].

#### 2.5 Digital Modulation Schemes

For a GSM system, its services only need first three layers of the well-defined ISO/OSI 7 (International Standards Organization Open Systems Interconnection) layer protocol which is a standardised protocol on networking accepted by nations around the world. This protocol has 7 layers, with each layer having a specific function [53]. Table 2-1 compares the ISO/OSI layers with the equivalent layer in the GSM standards. For this section of interest to be researched, the modulation layer is part of the first layer, being the physical layer; used for RF connection between a mobile phone device and the base station. This modulation layer is responsible for the modulation scheme employed in order to send the information over a given RF channel [36].
Upper Layers	7 6 5 4	Application Layer Presentation Layer Session Layer Transport Layer		Task of User Task of Fixed Network
Transport Service	3	Network Layer	Call Control Mobility Management Radio Resource Management	
	2	Data Link Layer	Segmentation / Concatenation Acknowledgement	Task of GSM- Network
	1	Physical Layer	Forward Error Correction Channel Coding Modulation	

#### ISO/OSI Model



Table 2-1: ISO/OSI 7 layers protocol [36]

In order to pass digital binary information over a RF channel we need to superimpose the binary waveform onto a RF carrier. This process is known as digital modulation where the information can be carried over a channel by means of altering any of the carrier's characteristics. This can be achieve by varying one or several of the carrier's phase (PM), frequency (FM) or amplitude (AM), where a few of these modulation schemes will be described below for reference. If a carrier channel is primarily considered as a frequency-selective fading channel, then PM or FM are used instead of AM, since amplitude changes are more sensitive than angle modulation that could occur in a fading channel[54].

Various methods known as keying methods are used to represent the binary on-off status of the digital modulation, which are: phase-shift keying (PSK), frequency-shift keying (FSK) and amplitude-shift keying (ASK) [54]. A few example of these keying methods will be briefly described as bellow:

### 2.5.1 Binary Phase-Shift Keying (BPSK)

BPSK is PSK that has two carriers out of phase with each other at the given data rate. They differ in phase by 180° and are represented easily on an I/Q diagram as shown in Figure 2-11.



Figure 2-11: Binary Phase-Shift Keying [54]

#### 2.5.2 Quadrature Phase-Shift keying (QPSK)

QPSK expands on BPSK by allowing phase changes split into four different quadrants. This allows for four carrier phases to be utilised as opposed to two carriers using BPSK. For maximum gain resolution when demodulating the waveform, all four of the carriers are exactly 90° out of phase from each other. All possible changes between phase states are shown in Figure 2-12 as well as the smaller circle states, indicating a no-change condition from the previous state. It is also noted that this modulation scheme now represents two bits where each state is referred to as a symbol. As each carrier is 90° out of phase from another, QPSK can be formed by taking two BPSK waveforms which have been shifted 90° from each other.



Figure 2-12: Quadrature Phase-Shift Keying [54]

## 2.5.3 Offset Quadrature Phase-Shift keying (OQPSK)

OQPSK follow similar principles for QPSK, using a two bits per symbol modulation scheme but only allows one of those bits to change at any given time by offsetting the data going into the BPSK generators by half a symbol, which in this case is one bit. By doing this the carrier states are changed so that a symbol cannot cause a 180° phase change as shown in Figure 2-13.



Figure 2-13: Offset Quadrature Phase-Shift Keying [54]

## 2.5.4 Gaussian Minimum-Shift Keying (GMSK)

For GSM, the modulation scheme specified is GMSK, therefore this research will focus on simulating this modulation scheme in later chapters. GMSK is an enhancement a MSK modulated waveform where the signal is filtered with a Gaussian filter of the correct bandwidth. This bandwidth is defined by the BT product. The states for GMSK can be seen in Figure 2-14.



Figure 2-14: Gaussian Minimum-Shift Keying [54]

## CHAPTER 3 BASIC FSS STRUCTURE SIMULATIONS AND MEASUREMENTS

This research explores the design of a secure electromagnetic building, focusing on buildings such as hospitals, embassies, cinemas and prisons. The novelty in this research was the investigation of a surface, which can be embedded into a wall or a window of a room/building to stop unwanted frequency bands. So the basic passive band-stop FSS has been researched to understand the FSS structure and also to familiarize the use of the CST simulation environment by designing a simple prison cell structure. This basic FSS design would be used for a secure building application in the following chapters, with the prison cell being explored as an example.

## **3.1 Band-Stop Filters**

Band-Stop FSS can filter out unwanted frequency bands which will be frequently used in this research; two examples are given to stop frequencies at 1.8GHz and 2.1GHz. Most a theoretical analysis methods for FSS, is not take into account arrays with finite size. These methods are often based on approximated arrays of infinite size using Floquet modes reducing to a single cell computation area, which used within the frequency domain solver in CST [55]. The unit cell boundary simulates conditions in the x and y directions and derives Floquet mode excitation. The use of these boundary conditions allows a rapid and accurate simulation of an infinite FSS in the directions of periodicity. For this reason we only need to construct a FSS geometry of single unit cell [56].

#### 3.1.1 Band-Stop FSS Unit Cell Tuned at 1.8GHz

A square loop FSS unit cell (50mm x 50mm) tuned at 1.8GHz was designed and fabricated on 1.6mm FR4 dielectric ( $\varepsilon_r = 4.5$ ,  $tan\delta = 0.01$ ) substrate as shown in Figure 3-1. These materials were chosen mainly because they are relatively inexpensive.



W(mm) 50 Single Square Loop FSS 5 2.6

Figure 3-1: Band-stop Single Square Loop FSS at 1.8 GHz



Figure 3-2: Transmission Response of the FSS at 1.8GHz

The simulation results were generated using the CST frequency domain solver showing that the FSS is tuned at 1.8GHz for a normal incidence angle (theta) of  $0^{\circ}$  with attenuation 46dB in the TE and TM mode in Figure 3-2. By varying the incidence angle (theta) in 10° intervals until 50°, the attenuation ranges between 27dB to 46dB in the TE mode as shown on graph in Figure 3-3.

A similar attenuation was seen ranging between 31dB to 46dB in the TM mode shown in Figure 3-4. All the simulated results have similar resonant frequencies with attenuations of greater than 27dB at different varying incidence angles.



Figure 3-3: Transmission Responses of the FSS at 1.8GHz in TE Mode



Figure 3-4: Transmission Responses of the FSS at 1.8GHz in TM Mode

#### 3.1.2 Band-Stop FSS Unit Cell Tuned at 2.1GHz

A square loop FSS unit cell (50mm x 50mm) tuned at 2.1 GHz was designed and fabricated on 1.6mm FR4 dielectric ( $\varepsilon_r = 4.5$ ,  $tan\delta = 0.01$ ) substrate with a 5mm plastic board ( $\varepsilon_r = 2.5$ ,  $tan\delta = 0.05$ ) attached to its back surface as shown in Figure 3-5.





Figure 3-5: Band-stop Single Square Loop FSS at 2.1 GHz



Figure 3-6: Transmission Response of the FSS at 2.1GHz

The simulation results were generated using the CST frequency domain solver showing that the FSS is tuned at 2.1GHz for a normal incidence angle (theta) of 0° with attenuation 36dB in the TE and TM mode in Figure 3-6. By varying the incidence angle (theta) in 10° intervals until 50°, the attenuation ranges between 18dB to 36dB in the TE mode showing a slight shift of the resonant frequency to the left as the incidence angles increases, Figure 3-7. A better performance of 31dB to 36dB in the TM mode was seen in Figure 3-8 with minimal shift of the resonant frequency. All the results simulated perform with similar resonant frequencies attenuations of greater than 18dB at different varying incidence angles.



Figure 3-7: Transmission Responses of the FSS at 2.1GHz in TE Mode



Figure 3-8: Transmission Responses of the FSS at 2.1GHz in TM Mode

The frequency characteristics of the FSS can be tuned by modifying the parameters of the substrate material. Manipulating the FSS layers reactive characteristics by incorporating tuning elements or re-arranging the structure geometry are also methods that can be employed [9]. In this single loop FSS design, changes to the thickness of the loop are used to alter the frequency response. Additionally, due to this symmetrically designed structure with respect to both x and y axes, its response of TM mode only slightly shifted from the desired resonant frequency.

#### 3.1.3 Band-Stop FSS Panel Tuned at 2.1GHz

This research focuses on special buildings requirements which can stop unwanted frequencies entering the building. In the example of a prison, the assumption has been made for a prison cell window being of dimension 1m x 1m, and therefore the FSS panel dimensions were chosen to be 1.2m x 1.2m, so that it can be attached to the surrounding frame. The purpose of this panel is to stop signals at 2.1GHz. To make the panel straightforward to manufacture and construct, the FSS was split into sixteen identical panels, each with a width of 0.3m and a height of 0.3m. On each small panel is an FSS with a 6x6 unit cell structure as shown in Figure 3-9.



Figure 3-9: FSS Panel

After CST simulations where carried out, actual measurements use a pair of transmitting and receiving horn antenna (Rohde & Schwarz HF906) which have a bandwidth between 1GHz to 18GHz, they connect with a vector network analyser were carried as a comparison to confirm the simulation results; the vector network analyse have been calibrated before take this measurement, this setup as shown in Figure 3-10. For each measurement a reference calibration was taken without the FSS and using the same procedure. For the transmission frequency range of interested, the instrument was then calibrated. The measurement results in Figure 3-11 compared closely with the simulated result of the unit cell in Figure 3-6 which both showing a band-stop response at 2.1GHz with an attenuation of 36dB.





Figure 3-10: Measurement Set Up for FSS Panel



Figure 3-11: FSS Panel Measurement Result

## 3.2 Modelled Prison Cell using Signal Layer FSS

A 3.0m x 3.0m x 3.0m metal box is constructed as an empty prison cell model using CST simulation software. For the purposes of this simulation the outer shell is assumed to be made of metal a 1.0m x 1.0m aperture window in the front wall of the box as in Figure 3-12 (a). A plane wave is used as the excitation signal, with the probe being used to receive signals located in the middle of the room as illustrated by Figure 3-12 (b). The prison cell was first simulated without an FSS in place as a reference by using the CST time domain solver giving the response in Figure 3-13.



Figure 3-12: (a) Metal Box without FSS and (b) Metal Box Model



Figure 3-13: Simulation Result for Metal Box without FSS

A 1.0m x 1.0m band-stop FSS panel tuned at 2.1GHz was then placed in the aperture as in Figure 3-14, and the same simulation conditions were used for comparison with the reference result. The frequency range of interest is between 0Hz and 2.7GHz.



Figure 3-14: Metal Box with FSS

Figure 3-15 shows the simulated electric field signal attenuation as being around 26dB at 2.1GHz after the FSS was added.



Figure 3-15: Simulation Result for Metal Box with FSS

The resonant frequency has been shifted slightly to the right and there is a broadening of the attenuating bandwidth around the resonant frequency. This is due to the nature of the structure interacting with the FSS design.

## 3.3 Summary

Two basic passive band-stop FSS have been been analysed; The first one attenuates signals by upto 46dB for normal incidence (theta =0, phi=0) at 1.8GHz. By varing the incidence angles, the antenuation ranges between 27dB and 46dB, which indicates that if the incident signal is stronger than 27dB, this FSS would be unable to filter out all the unwanted signal at some incidence angles. The second FSS can attenuate signal to 36dB for a normal incidence angle at 2.1GHz. By varying its incidence angle the attenuation range seen is between 18dB and 36dB. These FSS are both straightforward to manufacure and low in cost; so if a building does not require a high attenuation, they are the good chioces. To valiate the simulation results, the FSS panels are manufactured, with there measurement results have good agreement with the simulation results. Additionally, a metal box with a single layer FSS has been simulated to assess FSS performance at 2.1 GHz. The results concluded that this signal layer FSS panel can attenuate a signal by upto 26dB at the required frequency.

## CHAPTER 4 NUMERICAL MODELLING DEVELOPMENT

This chapter is intended to explain the framework of GSM as implemented for simulation in MATLAB, and to compare the simulation results with those reported in previous work. This GSM framework will be used to test reconfigurable switching FSS performance in Chapter 5. In order to speed up the modelling processing of this research, the use of software CST and Matlab will also be explored.

## 4.1 GSM Protocol Modelling

## 4.1.1 GSM Background

To begin the design of a simulation model in MATLAB the framework of GSM needs to be understood. GSM is an example of the second generation (2G), it brought the switch over from analogue to digital systems, which vastly improved voice calls in terms of privacy and quality. GSM operates on both 900MHz and 1800MHz frequency bands throughout the UK [57], with Vodafone and O2 networks using GSM 900 and Orange and T-Mobile networks using GSM 1800. GSM carrier frequencies are separated by 200 kHz have an uplink and downlink frequency range which is shown in Table 4-1. The uplink transmits from mobile device to base station, the downlink is vice versa.

	Uplink	Downlink	No. of physical channels
GSM 900	890915MHz	935960MHz	125
GSM 1800	17101785MHz	18051880MHz	375

Table 4-1: The Frequency Ranges, Offset, and Number of Physical Chanel for GSM900/1800

GSM technology uses the radio spectrum more efficiently than previous generations, so that users could transmit text/data and voice, with the optional choice of using their mobile phone abroad as well if required [58]. To do this it employs narrow band TDMA (time-division multiple-access), with each TDMA frame shown in Figure 4-1 being divided into eight bursts. These bursts consist of several trail and guard bits with the important 26 bit training sequence which is used as a timing reference and for multipath equalisation at the centre of burst, it being in the middle surrounded by data of 58 bits on each side [59].

The duration of a TDMA frame is 4.615ms, so each burst will take  $576.9 \,\mu$ s, and it has a bit rate of 271kbit/s giving 3.69  $\mu$ s for each bit duration in the burst [60].



Figure 4-1: Structure of a GSM TDMA Frame

From the GSM TDMA frame structure shown in Figure 4-1, the transmission part of the Matlab model is constructed by first encoding the speech data combining interleaving and differential encoding followed by GMSK (Gaussian Minimum Shift Keying) modulation of the signal [61]. The modulated signal is transmitted through the CAI (Common Air Interface) after up conversion by a frequency multiplier. The receiver part of the GSM model is implemented in reverse with a de-modulator followed by decoding with interleaving and differential techniques to reconstruct the original data sent. A model of the GSM system used in this research is shown as follows:



Figure 4-2: Model of GSM System

#### 4.1.2 Speech Signal Convolution Coding

Speech samples are analysed and processed in 20ms audio blocks by a speech encoder which compresses the data of a speech signal. This process is referred to as the Regular Pulse Excitation and Linear Predictive Coding (RPE-LPC) module in a GSM model. The speech encoder operates at 13 kbit/s which corresponds to 260 bits every 20ms [62].

These 260 bits are divided into two classes: Class I (182bits) and Class II (78bits) with Class I being split into two categories (Ia and Ib). This is due to the bits in Class Ia being more important than the bits contained in Class Ib and require extra encoding protection to prevent data errors before convolutional coding. To do this three parity bits are calculated for error detection using Class Ia and are added to the end of the Class Ia before being combined with Ib and an additional four tail bits to make the full Class I.

This now makes the frame of size 267 bits with only the Class I part requiring encoding using convolutional coding techniques. Once the Class I is input into the convolutional coder it adds redundant bits for every bit that enters it, so that it can be less prone to errors which can be better recovered by the receiver compared with systems that do not use convolution coding. After the convolutional coding, the Class I in the frame will come to 378 bits to make a total frame size of 456 bits [63] as shown in Figure 4-3.



Figure 4-3: Convolutional Coding

## 4.1.3 Interleave Simulation

The 456 bits which are output from convolutional coding are divided into eight equal time slots of 57 bits each, which are reordered. This has an advantage as if one time slot

burst is corrupted, then only one-eighth of each time slot burst is lost rather than a full time slot burst segment. Also this data still has a potential of being recovered successfully at the received end. This process is known as data interleaving. The convolutional coder and interleaving protects against the fading phenomenon that might happen over the channel.

In the GSM standard, each time slot burst has 114 data bits which consists of two 57 bit data blocks. In a frame these eight time slots bursts are interleaved with data from three consecutive data blocks referred to as A, B and C. If you take the example of the current four time slots and the next four time slots with Block B being the current data the following logic can be applied. The first four time slot bursts are allocated with starting data from Block B only populating the odds bits. The even bits come from the last part of data Block A. The remaining last part of data Block B is populated into then even sections of the next four time slot [62]. This is illustrated in Figure 4-4 showing where each data element gets divided into each time slot.



Figure 4-4: Interleaving Process

#### 4.1.4 Differential Encoding Simulation

Differential encoder assigns a polarity to the symbols. It converts the '0' and '1' symbols into equally distant aptitudes '+1' and '-1' respectively. Firstly, the '0' and '1' symbols in the burst input are fed into an XOR logical operator which produces a value of '1' only when the two input values are different and produces a value of '0' only when the two input values are the same [54] as shown in Table 4-2.

Input A	Input B	Output (X)
0	0	0
0	1	1
1	0	1
1	1	0

Table 4-2: True Table for Logical XOR Operator [54]

After this process the '0' and '1' symbols from this output are converted into '+1' and '-1' by the equation shown (4-1) below:

$$Y = 1 - 2X \tag{4-1}$$

Where  $X \in (0, 1)$ 

X	Y
0	+1
1	-1

Table 4-3: Logical Table for Differential Encoding [54]

Each frame includes eight bursts in GSM. For simplicity, one of the eight bursts in MATLAB is used as an example to show the difference between the input and output of the differential encoder in Figure 4-5 and Figure 4-6. The burst shows all 157 bits. This is broken down with two 57 bit data sections being set to zero as well as the bits required for tail and steal flags. The actual 26 bits training sequence required are kept to be the true values and all 9 guard bits are set to one.



Figure 4-5: Input Data of the Differential Encoder



Figure 4-6: Output Data of Differential Encoder

#### 4.1.5 GMSK Modulation Simulation

After the differential encoder, the data needs to be modulated with GSMK (Gaussian Minimum-shift Keying) which is widely used in GSM systems as a constant-envelop modulation method. To achieve this, data from the differential encoder is input into the Gaussian filter which is shown in Figure 4-7 below:



Figure 4-7: GMSK Modulator

A Gaussian impulse response in the Gaussian Filter is typically used for GMSK modulation which is designed for filtering out interference between adjacent signals in the frequency spectrum. This is calculated using the following (4-2) bellow.

$$G(t) = \frac{1}{2T} \left[ Q \left( 2\pi B \frac{t - \frac{T}{2}}{\sqrt{\ln 2}} \right) - Q \left( 2\pi B \frac{t + \frac{T}{2}}{\sqrt{\ln 2}} \right) \right]$$
(4-2)

Where B is the bandwidth of the Gaussian filter. The bit interval product (BT) is 0.3 in GSM which is used as the normalised bandwidth [60].

The Q function for the Gaussian impulse response can be obtained as shown,

$$Q(t) = \int_{t}^{\infty} \frac{1}{\sqrt{2}} \exp(-r^{2}/2) dr$$
 (4-3)

Where r is the output data from the differential encoder.

For a Gaussian Filter in GSM, a bit duration of *T* is given as follows

$$T = \frac{\text{The duration of a TDMA frame}}{\text{The bits contain in a TDMA frame}}$$
$$T = \frac{4.615\text{ms}}{1250\text{bits}}$$
(4-4)

 $T=3.692 \mu s$ 

For a BT of 0.3, the Gaussian impulse response is truncated, symmetrically around zero on the x axis, to four bits periods from -2T to 2T. In Figure 4-8 a graphical representation of the impulse response from the MATLAB simulation is shown.



Figure 4-8: Impulse Response of Gaussian Filter

After the signal passes through the Gaussian filter g(t) this would yield a function of b(t). In GMSK modulation the signal is made up of In phase and Quadrature phase components from the Gaussian impulse response where the phase shift function is given by:

$$\Phi(t) = \int_{t}^{\infty} b(t) dt \qquad (4-5)$$

Combining both the in-phase  $cos(\varphi(t))$  and quadrature phase  $sin(\varphi(t))$  the output of GMSK modulation can be obtained as follows:

$$\cos(\varphi(t)) + j\sin(\varphi(t))$$
(4-6)

To validate the GSM modulation simulation in MATLAB, a 12 bit repeating stream shown in Table 4-4 is used and which has been extracted from a report available on the Link Collaborative Research website [64].



The Data stream is represented graphically below Figure 4-9 using MATLAB.



Figure 4-9: Data Stream after Encoder in Matlab

After the data stream passes through the Guasian filter, the individual Gaussian shaped pulses are added together, obtaining function b(t). The bit interval product is set at 0.5 with bit duration of T = 1/2000 in the report, so these parameters are also used in the MATLAB to generate the same graph in Figure 4-10.



Figure 4-10: Stream of Bits Added After Passing through the Gaussian Filter

After function b(t) has been obtained, it is integrated with respect to the time yielding function  $\varphi(t) = \int_{t}^{\infty} b(t)dt$  in Figure 4-11.



The in Phase I(t) =  $cos(\phi(t))$  is represented graphically from MATLAB in Figure 4-12.



Figure 4-12: In Phase Sequence I(t) in MATLAB

The Quadrature phase  $Q(t) = sin(\phi(t))$  is represented graphically from MATLAB in Figure 4-13.



Figure 4-13: Quadrature Phase Sequence Q(t) in MATLAB

Figure 4-9 to Figure 4-13, illustrate the same results as the original report [64]. This validates the modulation part of the GSM MATLAB model.

## 4.1.6 Channel Simulation

In order to simulate a realistic channel for an active switched FSS, three things need to be considered; Phase, Amplitude and Noise. Noise can currently be ignored in the simulation as any BER (Bit Error Rate) in this system will be produced by time varying transmission phase of the FSS. Note that the BER in this thesis is the data before interleave compared to the data after de-interleave. This calculates how many bits are in error which is then divided by the length of the data transmitted to get the ratio.

The phase and attenuation can be switched by dividing up the signal channel into digitised samples. Depending on how many samples are used to divide up the signal when switching between phase and attenuation states, a switching frequency for the FSS can be determined, and this will analysed in Chapter 5.

#### 4.1.7 Low-Pass Filter Simulation

A low-pass digital filter is used to filter out the energy within the side bands in frequency spectrum of the different switching frequency plot. For the case of this research, the cut off frequency will be tested a four different filter bandwidth, where a Hamming Window function has been employed in the low-pass filter to obtain a zero gain value outside of the chosen frequency band in the Fourier spectrum. More details about these will be explained in Chapter 5.

#### 4.1.8 **GSM Demodulation Simulation**

The Channel Impulse Response (CIR) in the demodulation process ensures successful equalisation which can remove Inter-Symbol Interference (ISI) in the received signal. The CIR is based on the special 26 bits known as training sequences [65]. In GSM there are eight different training sequences which can be used depending on the time slot used as follows:

Training Sequence Code (TSC)	Training Sequence Bits
0	0,0,1,0,0,1,0,1,1,1,0,0,0,0,1,0,0,0,1,0,0,1,0,1,1,1
1	0,0,1,0,1,1,0,1,1,1,0,1,1,1,1,0,0,0,1,0,1,1,0,1,1,1
2	0,1,0,0,0,0,1,1,1,0,1,1,1,0,1,0,0,1,0,0,0,0,1,1,1,0
3	0,1,0,0,0,1,1,1,1,0,1,1,0,1,0,0,0,1,0,0,0,1,1,1,1,0
4	0,0,0,1,1,0,1,0,1,1,1,0,0,1,0,0,0,0,0,0
5	0,1,0,0,1,1,1,0,1,0,1,1,0,0,0,0,0,1,0,0,1,1,1,0,1,0
6	1,0,1,0,0,1,1,1,1,1,0,1,1,0,0,0,1,0,1,0
7	1,1,1,0,1,1,1,1,0,0,0,1,0,0,1,0,1,1,1,0,1,1,1,1,0,0

Table 4-5: Eight Types of GSM training sequences [66]

The different training sequences help to distinguish between similar simultaneous signals arriving at the receiver at the same time. A training sequence consists of 16 bits to constitute the frame synchronization word in the middle and 5 bits at each ends to keep auto-correlation and frequency oscillation low. The first 5 bits at the beginning of the training sequence are copied from the last 5 bits in the centre 16 bits. The last 5 bits at the end of the training sequence are copied from the beginning 5 bits in the centre 16 bits. An example of a Training Sequence Code 1 (TSC1) is shown in Figure 4-14.



An estimate of CIR shown in Figure 4-15 can be obtained by correlating the received training sequence (16 bits) with a replica training sequence (26 bits) known at the receiver.



Figure 4-15: Estimated Channel Impulse Response

A rectangular window is slid over the estimated CIR across the length over the whole estimated response to calculate the energy in the window and find the maximum energy location [60].

$$E_{i} = \sum_{k=0}^{K-1} |h_{i+k}|^{2}$$
(4-7)

Where *K* is the window size, and typical GSM equalization use K = 5 [60].

When  $E_i$  in (4-7) reaches the maximum value, the maximum energy window start location *i* is obtained. Then the peak section of the CIR ( $h_n^{est}$ ) can be calculated in (4-8) and shown in Figure 4-16.

$$h_n^{est} = h_{i+n} \tag{4-8}$$

Where n = 0, 1, ... K - 1



Figure 4-16: The Peak of the CIR within the Window Size

The location of this peak can then be used for the matched filtering process in equation (4-9) along with locating the start position of the received burst for synchronising the received input data due to the peak position being the centre point of the training sequence in any given burst.

$$s = r * h^{est'} \tag{4-9}$$

where r is the received input data synchronised from the located start position and  $h^{est'}$  is the transposed CIR used by the filtering process.

The output *s* from the matched filtering process is the down sampled MSK symbols required for further decoding. The received input data r contains x samples compared to *s* due to the down sampling of the filtering process. x is also referred to as the sample rate.

## 4.1.9 MLSE Detection

The Maximum Likelihood Sequence Estimator (MLSE) is implemented as a Viterbi equaliser which is based on the modified Ungerboek algorithm [67]. This section of the

receiver handles the actual detection of the received sequence which is fed from the matched filtered and down sampled signal. This input signal is a sequence of samples which contains one sample for each transmitted symbol due to being down sampled first. The other information required by the Viterbi equaliser is the autocorrelation of the estimated CIR obtained during the matched filtering process. Using this information with a Viterbi equaliser can produce an output which is an estimate of the most probable sequence of the transmitted binary symbols.

## 4.1.10 Differential Decoder Simulation

A differential decoder converts the '-1' and '+1' symbols into '0' and '1' respectively. Firstly, the '1' and '-1' symbols from the output of demodulation are converted into '0' and '1' by equation (4-10) as shown below:

$$Y = \frac{1 - x}{2} \tag{4-10}$$

Where  $X \in (-1, 1)$ 

X	Y
-1	1
+1	0

Table 4-6: Logical Table for Differential Encoding

The '0' and '1' symbols in the burst input are fed into an XOR logical operator which produces a value of '1' only when the two input values are different and produces a value of '0' only when the two input values are same [54] as shown in above Table 4-6. The same burst in the differential encoding simulation (Section 4.1.4) is simulated in MATLAB as an example to show the difference between in the input and output of the differential Decoder in Figure 4-17 and Figure 4-18.



Figure 4-17: Input Data of the Differential Decoder



Figure 4-18: Output Data of the Differential Decoder

## 4.1.11 De-interleave Simulation

In the interleave simulation (section 4.1.3), the 456 bits are portioned into eight time slots of 57 bits each. The slots are then reordered and allocated into two 57 bits sections in one

burst to avoid the data being corrupted. In the de-interleave simulation, using the first 114 data slot as an example, the block is divided into even and odd bits. All even bits go to W4 in block A and all odd bits go to X0 in block B. This is illustrated in Figure 4-19.



#### 4.1.12 Convolution Decoding

After performing de-interleaving, each block contains 456 bits which are divided into two classes: Class I (378 bits) and Class II (78 bits) before it can be further processed. Only Class I requires decoding using convolutional decoding as Class II is used directly in the encoding process described in Section 4.1.2.

Once the data from Class I is input into the convolutional decoder it will reduce the redundant bits for every bit that enters it, with Class I becoming 189 bits from its received 378 bits. Following this process, Class I is further split into two categories (Ia and Ib), due to Class Ia being more important than the information contained in Class Ib.

Class Ia contains three parity bits which can be used to check if any data has been corrupted and further correction can be applied if required but are not used in this simulation.

At the end of Class Ib the extra four tail bits which were added by the sending system can be ignored and are no longer required. Finally Class Ia of 50 bits and Class Ib of 132 bits can be reconstructed with Class II which remains at 78 bits to recover back the original speech signal of 260 bits.



Figure 4-20: Convolutional Decoding

## 4.2 Software Environment

In this research, modelling simulation work plays an essential role regarding the evaluation of the design created for a FSS and the BER for a reconfigurable switching FSS. Commercial tool for the FSS design are utilised within a software suite called CST Microwave Studio. The sophisticated software can carry out electromagnet static, lowfrequency and high-frequency simulations based on the Finite Integration Technique (FIT). The FSS models have been designed in CST which can output 1D or 2D/3D results. The Scattering Parameters (S-Parameters) in the 1D result are very important. There is the reflection (S11) and transmission (S12) coefficients between the incident and reflection waves. Each parameter can be represented by real/imaginary parts, absolute and decibel value and phase. The results in decibels for the S-parameter are  $20 \log(S_{i,j})$ . The excitation wave travels in the ports with a variety of patterns called modes. Normally, there are three types of modes in a waveguide: Transverse Electric and Magnetic (TEM) mode, TE (Transverse Electric) mode and TM (Transverse Magnetic) mode. TEM mode is the direction of propagation, perpendicular to the electric field and magnetic field. TE mode is the direction of propagation, being only perpendicular to the electric field. TM mode which is opposite to TE mode, where the direction of propagation is only perpendicular to the magnetic field [68]. In the Figure 4-21, the 3-D wall surface are used as example to demonstrate these three modes.



Figure 4-21: TEM, TE and TM Polarisation

CST Microwave Studio can be used as a tool for accurate responsive 3D simulations of high frequency models which operate over a vast range of frequencies [18]. It will be utilised to observe the propagation of a radio wave through a FSS wall in an external to internal 3D environment. CST is also used to analyse plane wave incidence fired at the chosen FSS model obtaining its reflection and transmission characteristics [56].

The software used to simulate and analyse the BER for the reconfigurable switching FSS is MATLAB, which is an interactive environment used for numerical computation, visualization and programming. Programming scripts were developed to model a simulation of a GSM channel which could be used to measure the total BER of any given test input data sent over the simulated channel. This was further enhanced by exploring the characteristics of the channel by emulating the switching active FSS design with the results being clearly represented in 2D surface graphical form.

## 4.3 Summary

This chapter firstly introduced the background of GSM, to understand uplink and downlink for GSM 900 and GSM 1800, with the use of TDMA to transmit text, data and voice and the structure of a TDMA Frame being illustrated.

Secondly, the structure of the whole GSM system model has been shown with each part of the structure explained in detail. Also, the simulation results from MATLAB has been compared with the results extracted from an interest report to prove the GSM system created in MATLAB is correct and can be employed to test the reconfigurable switching FSS performance.

The major commercial software used for this research are CST Microwave Studio and MATLAB, with a brief outline of their functions being given for each in this chapter.

# CHAPTER 5 RECONFIGURABLE FSS FOR USE IN SECURE ELECTROMAGNETIC BUILDING

Frequency Selective Surfaces (FSS) have been a topic of research for many decades, for applications in large area filters [69-71], absorbing materials [72], and for use in the building environment [73]. There has been significant interest in designing reconfigurable periodic surfaces.

Generally, FSS are designed to either pass or stop electromagnetic waves over a range of frequencies. Reconfigurable FSS offer the advantage of flexibility by changing the FSS frequency response using an external bias signal i.e. voltage/current.

In this research, FSS has been investigated to act as impairment to mobile/cell phone signals for applications where communication is not wanted (i.e. hospitals, prisons etc.), where full electrical shielding of such signals may not be practical. It was shown in [74], that in areas of good mobile/cell phone coverage there would need to be >60dB of attenuation of the signal before the phone would not be able to communicate with the Base Station Transceiver (BTS). To use FSS with these requirements is very difficult in practice, due to manufacturing tolerances, angle of incidence and polarization effects.

The proposed solution is to make use of reconfigurable FSS in a manner that will corrupt the mobile/cell phone signal, such that the receiver cannot determine the data which is transmitted. This research will examine how this may be carried out for the GSM protocol even when a desirable >60dB attenuation cannot be achieved. Figure 5-1 illustrates the scenario of an FSS inserted into a perfectly conducting wall of a room or building. It is assumed that no energy can propagate into the room except through the FSS.


Figure 5-1: Illustration of FSS Embedded with the Wall of a Building

The FSS transmission properties are such that the transmission coefficient is time varying and complex, given as (5-1).

$$\tau(t) = |\tau(t)|e^{j\emptyset(t)}$$
(5-1)

Where  $\tau$  the transmission coefficient and  $\phi$  is the phase of the transmission coefficient.

The GSM protocol uses a combination of spatial, frequency and time domain multiplexing, however, for simplicity we will only consider the TDMA aspect of GSM. It is well known that a GSM "frame" is split into eight "bursts". The frame time is 4.6ms and the burst time is 0.577ms. It is assumed that each phone is allocated one burst per frame. Within each burst the signal that is transmitted is made up of binary information, which conveys the data as well as synchronization bits and training sequence bits at a data rate of approximately 270.8kbits/s. As previously described in Chapter 4.1 the binary signal is differentially encoded then modulated using Gaussian Minimum Shift Keying (GMSK) creating a baseband signal before being RF modulated to the appropriate transmission frequency.

The proposed technique is to use the time varying transmission response of the FSS to corrupt the GMSK modulated signal. The GSM protocol assumes that the channel in which the signal is propagating through is relatively constant, so if the channel response can be impaired appropriately with use of a FSS, it should be possible to corrupt the signal. For simplicity it is assumed that the FSS transmission response will vary periodically with time at a switching frequency fs, with the concept first being modelled using the GSM simulator described previously in Chapter 4.1.

# 5.1 GSM Simulator Using MATLAB

In Chapter 4.1, the model of a GSM system has been created in MATLAB, with the model being able to simulate different scenarios required. Firstly, this model enables fast simulation times to sweep all the different combinations of switching frequencies with corresponding phase values. Secondly, this model will allow for optimum values to be obtained, maximising BER which are required when designing phase characteristics of the active switching FSS model. Finally, this model is further verified once a physical FSS model is built for true environment testing which should closely match the simulated results from MATLAB.

In Chapter 4.1.6 the channels simulation mentioned that the phase and attenuation can be switched by dividing up the signal channel into digitised samples. Depending on how many samples are used to divide up the signal when switching between phase and attenuation states of the FSS, a switching frequency can be determined. The maximum switching frequency of the FSS is given below:

$$f_{Maximum Switching Frequency} = \frac{1}{2 * Bit Duration/Sample Rate}$$
 (5-2)

Where the bit duration is given by  $3.69\mu s$  from a previously calculated Equation (4-4) in Chapter 4.1.5. For each signal switched from one state to another state the minimum of one bit duration per state is required to obtain maximum switching. For example if the sample rate was equal to 20, the maximum switching frequency of the FSS would be 2.71MHz.

One of the eight burst are employed as an example for the switching technique which originally is 156 bits. After the data has been divided into digitised samples, if the sample rate is 20, then a total of 3120 sample points are used. In this research, two cases will be compared. First where in the data is not interleaved and second where the data has been interleaved before entering into the differential encoder which is introduced in Chapter 4.1.3.

When a randomly generated data stream with interleaving and convolutional coding, passes through the GSM modulation and enters the GSM Channel the phase represented graphically from MATLAB can be seen in Figure 5-2 to Figure 5-4. The signal is transmitted through a FSS with a transmission coefficient magnitude of 0dB and the

transmission phase varying from  $\pm 60^{\circ}$ . Figure 5-2 shows the phase before the channel switching; Figure 5-3 is the phase switching at the maximum switching frequency of 2.71MHz and Figure 5-4 is the phase switching at switching frequency of 271kHz.



Figure 5-2: Phase before Switching, Interleaving and Convolutional Coding



Figure 5-3: Phase Switching at 2.71MHz, Interleaving and Convolutional Coding



Figure 5-4: Phase Switching at 271kHz, Interleaving and Convolutional Coding

Now the discrete time domain of the signal for its phase is understood by the two phase states being switched, the frequency spectrum of channel can be analysed before switching which is shown in Figure 5-5. When a randomly generated data stream is switched by the maximum switching frequency, the frequency spectrum is shown in Figure 5-6 with the spectrum comprising of the original baseband data plus the sidebands are odd multiples of the switching frequency, making the first sideband at 2.71MHz. The frequency spectrum at the middle of Figure 5-6 compared with the frequency spectrum before the switching in Figure 5-5 has been attenuated 41%.



Figure 5-5: Frequency Spectrum before Switching, Interleaving and Convolutional Coding



Figure 5-6: Frequency Spectrum of the Signal Switching by 2.71MHz

When the signal is switched at 271kHz, the frequency spectrum can be shown as in Figure 5-7 with the spectrum comprising of the original baseband data plus harmonics spaced n\*271kHz apart, where n is an odd integer in the ideal case, making the first harmonics at 271kHz and second harmonics at 813kHz and so on. The frequency

spectrum at the middle of the Figure 5-7 compared with the signal before the switching in Figure 5-5 has been attenuated 10%.



Figure 5-7: The Frequency Spectrum of the Signal Switching at 271kHz

As illustrated in Figure 5-7, if the signal of the channel has been switched high enough, the significant sidebands of energy which could distort the recovering of the signal are beyond the predefined bandwidth of the receivers filter, making the process easy to be filtered out by the GSM receiver. The bandwidth of filter may vary depending on the receiver topology used which is very important as impacts the overall BER. When the filter is applied the signal is easily demodulated, assuming there is no significant noise on the signal. So in this research, a few bandwidths are chosen to give examples for their BER which are:

- Half the GSM bandwidth (135kHz)
- GSM bandwidth (270kHz)
- One and an half times the GSM bandwidth (405kHz)
- Two times the GSM bandwidth (540kHz)

For the above bandwidths a set hamming window will be used for all the digital filters. The hamming window is represented as follows,

$$\omega(n) = 0.54 - 0.46 \, \cos\left(2\pi \frac{n}{N}\right) \tag{5-3}$$

Where  $0 \le n \le N$ , the window length is L=N+1.

# 5.2 Frequency Spectrum of Channel with Interleaving

Firstly, from Figure 5-8 to Figure 5-11 the frequency spectrum of the channel with an applied bandwidth filter of 135kHz will be used as an example for its BER. For the following it is assumed as above that the switching frequency would be the maximum switching frequency at 2.71MHz. In Figure 5-8 the red line represents the filter in the receiver which can filter out the 'in band' signal with its amplitude being dropped 43% from the original transmission channel before switching. Assuming that is had not been attenuated beyond the sensitivity of the receiver, this would allow for the attenuated baseband signal to be recovered easily, with the signal which is received by the GSM receiver being the same as the signal being sent through the GSM channel, therefore creating no bit errors in this case i.e. a BER equal to zero.



Figure 5-8: The Signal as Switching Frequency at 2.71MHz

If the switching frequency is changed to 271kHz as in Figure 5-9 the sidebands of energy are slightly overlapping within the bandwidth of the receiver filter, after the signal is filtered the sidebands remain inside the receiver filter bandwidth which makes the receiver difficult to filter out the unwanted sideband energy by the GSM receiver. This can cause the attenuated baseband signal to be received in-correctly. In this case there is only a reduced amount of sideband signals which has not been filtered out, meaning that the signal can still be recovered by the Viterbi Algorithm used by GSM, giving a BER of 0% being obtained with the energy level dropping 10%.



Figure 5-9: The Signal as Switching Frequency at 271kHz

If the switching frequency is changed to 135.5kHz, a different observation can be seen from Figure 5-10 which shows the sidebands of energy interrupting significantly the 'in band' signal when the switching frequency is at 135.5kHz. The sidebands now contained in the bandwidth of the receiver filter, and combined with the 'in band' signal, which distorts the recovery of the signal giving a BER of 6.1% with the signal energy level being dropped by 5.3%.



Figure 5-10: The Signal as Switching Frequency at 135.5kHz

Figure 5-11 shows the switching frequency now being changed to 67.75kHz. The sidebands signal are contained in the bandwidth of the receiver filter, which distorts the recovery of the signal giving a BER of 46.5% with the signal energy level being dropped by 2%.



Figure 5-11: The Signal as Switching Frequency at 67.75 kHz

Comparing the BER of the switching frequency changing between 2.71MHz to 67.75kHz from Figure 5-8 to Figure 5-11, when the switching frequency decreases, the sidebands of energy interrupts significantly the 'in band' signal, causing the BER to be increased. Whereas the 'in band' signal's amplitude when compared to the original transmission channel decreases as the switching frequency increases.

Secondly, from Figure 5-12 to Figure 5-15 the frequency spectrum of a channel with an applied bandwidth filter of 270kHz is used as an example for its BER.

If the switching frequency is 2.71MHz, a BER of 0% is obtained with the energy level dropping 43%.



Figure 5-12: The Signal as Switching Frequency at 2.71MHz

If the switching frequency is changed to 271kHz, a BER of 0% is obtained with the energy level dropping 10%.



Figure 5-13: The Signal as Switching Frequency at 271kHz

If the switching frequency is changed to 135kHz, a BER of 42% is obtained with the energy level dropping 1%.



Figure 5-14: The Signal as Switching Frequency at 135.5kHz

If the switching frequency is changed to 67.5 kHz, the BER of 44.6% is obtained with the energy level dropping 0.5%.



Figure 5-15: The Signal as Maximum Switching Frequency at 67.75kHz

From Figure 5-12 to Figure 5-15, the BER follows the same trend as a filter bandwidth of 135kHz. As the switching frequency decreases, the BER rate is increased. As previously stated the BER using a switching frequency of 135.5kHz applied with a bandwidth filter of 135 kHz is 6.1%. If compared with as bandwidth of a filter changed to 270kHz, the BER increases to 42%, which indicates the importance of the bandwidth used in the filter which will decide the effect on the BER received.

The above were examples of switching with a two state FSS between phase of  $60^{\circ}$  and  $-60^{\circ}$  do not show the wide range of effects at different switching phases across different switching frequencies. To achieve this, the BER of a number of randomly generated GSM signals were transmitted through a surface by varying the switching frequency and transmission phase to plot a 2-D surface of BER. The x-axis is the phase difference in degrees between two states e.g.  $\pm 60^{\circ}$  equals  $120^{\circ}$  phase difference, the y-axis is the switching frequency in kHz and the z-axis is the BER which is represented as a percentage. The BER shown is the average taken from a set number of randomly generated GSM signals tested at a given frequency and phase switching sample. The 2-D surfaces of BER plotted in Figure 5-16 to Figure 5-18 are simulated in MATLAB using 1 random seed, 10 random seeds and 100 random seeds respectively. Comparing these three figures, the figure that uses 10 random seeds is very similar with 100 random seeds, concluding that the figure using 100 random seeds has already converged to a stable average result, making it accurate enough to analyse the BER.



Figure 5-16: A 2-D Surface Plot of BER for 1 Random Seed



Figure 5-17: A 2-D Surface Plot of BER for 10 Random Seeds



Figure 5-18: A 2-D Surface Plot of BER for 100 Random Seeds

All the following results have been generated using 100 pre-set random seeds so that the same data is used to compare the BER between different filter bandwidths, phases and switching frequencies.

# 5.3 2-D Surface Plots of BER with Interleaving

When the bandwidth of the receiver filter is half of the GSM bandwidth (135 kHz), the resulting 2-D BER is shown in Figure 5-19.



Figure 5-19: BER (%) using Bandwidth Filter of 135kHz with Interleaving

When the bandwidth of receiver filter is the GSM bandwidth (270kHz), the resulting 2-D BER is shown in Figure 5-20.



Figure 5-20: BER (%) using Bandwidth Filter of 270kHz with Interleaving

When the bandwidth of receiver filter is one and a half times the GSM bandwidth (405kHz), the resulting 2-D BER is shown in Figure 5-21.



Figure 5-21: BER (%) using Bandwidth Filter of 405kHz with Interleaving

When the bandwidth of receiver filter is double the GSM bandwidth (540kHz), the resulting 2-D BER is shown in Figure 5-22.



Figure 5-22: BER (%) using Bandwidth Filter of 540kHz with Interleaving

It can be seen from Figure 5-19 to Figure 5-22 that significant BER can be achieved over a large range of switching frequency and transmission phases. Particular regions of interest are the low and high frequency "cut-off". It can be seen that some signal impairment occurs for switching frequencies as low as 1 kHz for different bandwidths of receiver filter, but the high frequency cut-off varies depending on the different bandwidth of the receiver filter. When the bandwidth of the receiver filter is increased above the normal GSM bandwidth, the high frequency cut-off increases due to side band energy interference. An example of this can be seen when the phase difference is 120 °, the high frequency cut off at which the BER starts to fall back to zero is 150.5kHz when the bandwidth is 135kHz, 270.8kHz when the bandwidth is 270kHz, 386.9kHz when the bandwidth is 405kHz and 541.7kHz when the bandwidth is 540kHz. This means when the bandwidth of the receiver filter is increases due to the signal 'in band' being degraded causing inaccurate data recovery.

### 5.4 Frequency Spectrum of Channel without Interleaving

Next the results of a randomly generated data stream without interleaving are shown, after GSM modulation and entering the GSM Channel. This is then compared with the channel being switched and filtered with the bandwidth of the filter being 270kHz. As before the switching was between  $\pm 60^{\circ}$ , only the switching frequency varies from Figure 5-23 to Figure 5-25. The first example is a switching frequency at 271kHz. Figure 5-23 shows the red line, representing the filter in the receiver, with the BER being zero in this case.



Figure 5-23: The Signal as Switching Frequency at 271 kHz



If the switching frequency is 135.5kHz as in Figure 5-24, the BER increases to 49%.

Figure 5-24: The Signal as Switching Frequency at 135.5kHz

If the switching frequency is 67.75kHz as in Figure 5-25, the BER increases further to 51%.



Figure 5-25: The Signal as Switching Frequency at 67.75kHz

Comparing the results of 'interleaving on' and 'interleaving off' on the frequency spectrum of the different switching frequency with an applied bandwidth filter of 270kHz, when the switching frequency is 271kHz, the BER is zero for both of 'interleaving on'

and 'interleaving off', due to the sideband signal not being significantly distorting the 'in band' signal. When the switching frequencies decrease, the sideband signals are contained in the bandwidth of the receiver filter, and the signal cannot be recovered by the GSM system. Examples of this can be seen at 135.5kHz, with a BER of 42% for the 'interleaving on' case and a BER of 49% for the 'interleaving off' case. When the switching frequencies are 67.75kHz, the BER is 44.6% for the 'interleaving on' case and the BER is 51% for the 'interleaving off' case. So from these examples, the 'interleaving off' case.

# 5.5 2-D Surface Plots of BER without Interleaving

Figure 5-23 to Figure 5-25 have been shown as an example of switching with a two state FSS between phase of  $60^{\circ}$  and  $-60^{\circ}$  without interleaving to observe the effects on the frequency spectrum. The wide range of effects at different switching phases across different switching frequencies without interleaving are plotted in the 2-D surface of the BER. The x-axis is the switching frequency in kHz, the y-axis is the phase difference in degrees between two states i.e.  $\pm 60^{\circ}$  equals  $120^{\circ}$  and the z-axis is the BER which is represented as a percentage. The BER shown is the average taken from a set number of randomly generated GSM signals tested at a given frequency and phase switching sample. The 2-D surfaces of BER are plotted in Figure 5-26 to Figure 5-29 which are simulated in MATLAB using 100 random seeds.



Figure 5-26: BER (%) using Bandwidth Filter of 135kHz without Interleaving



Figure 5-27: BER (%) using Bandwidth Filter of 270kHz without Interleaving



Figure 5-28: BER (%) using Bandwidth Filter of 405kHz without Interleaving



Figure 5-29: BER (%) using Bandwidth Filter of 540kHz without Interleaving

When comparing the 'on' and 'off' modes of interleaving the outer perimeter trend of the BER plot appears to be same as shown in Table 5-1. When the sending signal is interleaved, the receiver operates more effectively after decoding for recovery, which is observed with the BER being lower at small phase shifts and at slower switching frequencies.

	W	ith Interleavi	ng	Without Interleaving			
Bandwidth of Receiver Filter	$F_{min}(kHz)$	F <sub>Max</sub> (kHz)	Φ (Degree)	F <sub>min</sub> (kHz)	F <sub>Max</sub> (kHz)	Φ (Degree)	
135kHz	0.85	300.9	36	0.85	300.9	36	
270kHz	0.85	451.4	40	0.85	451.4	40	
405kHz	0.85 541.7		40 0.85		541.7	40	
540kHz	<b>kHz</b> 0.85 677.1		40	0.85 677.1		40	

Table 5-1: Comparison of the 'on' and 'off' Mode of Interleaving

# 5.6 Summary

This chapter follows on from the GSM systems explained in Chapter 4, where phase switching can be achieved by using a reconfigurable switched FSS over the GSM channel. The maximum switching frequency of the FSS is 2.71MHz. The frequency spectrum of the switched GSM channel would represent the phase switching technique that shifts the energy at the carrier frequency to the sidebands. Observations are concluded on how the overall BER is affected by using different bandwidths of the receiver filter as well as variation of the switched frequencies between the phase states. Simulation results from MATLAB showed when the switching frequency and transmission phase have also been given, with the switching frequency of signal impairment starting from a lower boundary at 1kHz and upper boundary which would depend on the bandwidth of the receiver filter. This was seen when the bandwidth of the filter was increased, the upper boundary also increased up to the point at which higher frequencies irrelevant to the recovery of a GSM transmitted signal.

# CHAPTER 6 SYSTEM MEASUREMENT TO TEST SWITCHING FSS WITH GSM SIGNALS

In this chapter, the design and test of two reconfigurable switching FSS panels are discussed, with the measurement setups being introduced as well. Finally, 2-D surface plots of the BER results for the measurements are shown.

# 6.1 Reconfigurable Single Polarization FSS Unit Cell Design

Reconfigurable single polarization FSS unit cell design and simulations were carried out using CST microwave studio as illustrated in Figure 6-1. Square loop has been employed as a band-stop filter, with the periodicity of the unit cell being 12mm; the width of the loop being 1mm and the gaps between unit cells being 1mm. The loop is fabricated on 1.6mm FR4 dielectric ( $\varepsilon_r = 4.5$ ,  $tan\delta = 0.01$ ) substrate with the gap between each unit cell being linked by a BB857 silicon tuning diode (Appendix V), used as a tuning element with its capacitance change being controlled from 0.45pF to 7.2pF.



Substrate: FR4, Thickness (h): 1.6mm

Figure 6-1: Front and Side View of the Reconfigurable Signal Polarization FSS Unit Cell

From Figure 6-2 and Figure 6-3, the reconfigurable FSS can be seen to sweep the frequency response from 0.9GHz to 3.1GHz by varying the capacitance which could cover the 2G and 3G mobile phone signal frequency range. Additionally, from the data sheet (Appendix V) for the tuning diode, when the voltage increases, the capacitance is reduced. Therefore for the operation of the transmission response, the desired resonant frequency of the band-stop filter increases as the voltage is increased across the diode.



Figure 6-2: Transmission Response for Reconfigurable Signal Polarization FSS Unit Cell



Figure 6-3: Phase Response for Reconfigurable Signal Polarization FSS Unit Cell

For this section the focus will be on the 2G GSM protocol at 1.8GHz. To acheive this the capactiance of the diode has been swept in CST to find the optimun attenuation at the resonance frequency of 1.8GHz. After sweeping, the capactiance is found to be 1.5pF at the resonance frequency with the attenuation being 43.8dB which is shown in Figure 6-4. The phase response can also been seen in Figure 6-5, with the positive phase response being 76° and -84°, giving an overall phase difference of 160°. Figure 6-6 shows the single polarization reconfigurable FSS only influencing GSM signals arround the tuned selective frequency of 1.8GHz. i.e when the voltage is varied between two states the capatictance change causes a difference in phase of 160° around 1.8GHz. However in the Tetra band range (400MHz), the phase difference is very small being only 13°, which is not enough to produce a significant BER.



Figure 6-4: Transmission Response of FSS Unit Cell Tuned at 1.8GHz



Figure 6-5: Phase Response of FSS Unit Cell Tuned at 1.8GHz



Figure 6-6: Phase Response of FSS Unit Cell at varying Capacitances

# 6.2 Reconfigurable Single Polarization FSS Panel Design

The single-polarized reconfigurable FSS panel has been manufactured into a prototype FSS shown in Figure 6-7 (a). The size of board is 24.5cm x 24.2cm, comprising of 20x19 individual unit cells linked by 380 variable capacitance diodes (BB857) soldered onto the PCB board. The surrounding traces are to be utilised for the power terminals. A simplified version of the FSS panel structure can also be seen graphically in Figure 6-7 (b), where all red coloured unit cells connect to the positive terminal of power supply, and the blue coloured unit cells connect to the negative terminal of power supply.



Figure 6-7: Reconfigurable Single Polarization FSS Panel

# 6.3 **Reconfigurable Single Polarization FSS System Measurement**

Measurements will be carried out to validate the simulation results. The setup of the measurement is shown in Figure 6-8. The transmission properties were characterized using a free-space measurement technique, consisting of two wideband horn antennas connected to an HP8720 vector network analyser. The transmit antenna was mounted above and the FSS, at a distance of approximately 60cm from the FSS. The FSS was placed on the centre of the metal plate which has an aperture to fit the FSS in. The FSS and metal plate were placed on a low permittivity foam spacer. The receive antenna was mounted 60cm below the FSS. This provides RF illumination close to normal incidence.

The system was calibrated by measuring the transmitted power over frequency range when the FSS was not present, by doing this, diffraction which is measured from the edges of the finite metal sheet are included in the calibration when the FSS was in plate, by varying the voltage across the varactor diodes the amplitude and phase of the transmission coefficient can be altered as the resonant frequency of the FSS is tuned.



Figure 6-8: Measurement Set Up for Reconfigurable FSS Panel

Voltage (V)	Transmission Response (dB)	Phase (Degree)	Voltage (V)	Transmission Response (dB)	Phase (Degree)	Voltage (V)	Transmission Response (dB)	Phase (Degree)
0	-17	108	9.5	-20	-123	19	-19	-114
0.5	-18	113	10	-20	-122	19.5	-19	-114
1	-19	118	10.5	-20	-121	20.0	-19	-114
1.5	-21	127	11	-20	-120	20.5	-19	-114
2	-22	138	11.5	-20	-120	21	-18	-113
2.5	-24	154	12	-20	-119	21.5	-18	-113
3	-24	170	12.5	-20	-119	22	-18	-113
3.5	-25	-171	13	-19	-118	22.5	-18	-113
4	-24	-158	13.5	-19	-118	23	-18	-113
4.5	-23	-150	14	-19	-117	23.5	-18	-112
5	-23	-143	14.5	-19	-117	24	-18	-112
5.5	-22	-139	15	-19	-116	24.5	-18	-112
6	-22	-135	15.5	-19	-116	25	-18	-112
6.5	-22	-132	16	-19	-116	25.5	-18	-112
7	-21	-130	16.5	-19	-116	26	-18	-111
7.5	-21	-128	17	-19	-115	26.5	-18	-111
8	-21	-126	17.5	-19	-115	27	-18	-111
8.5	-21	-125	18	-19	-115	27.5	-18	-111
9	-20	-124	18.5	-19	-115	28	-18	-111

Table 6-1: The Transmission and Phase Response for the FSS against Voltage

In Table 6-1, the DC voltage has been varied from 0V to 28V which provided attenuation variation between 17.74 dB to 25.06 dB and a phase variation between  $+170^{\circ}$  to  $-171^{\circ}$ , where the highlighted red result indicates the phase change for the resonant frequency of 1.8GHz at 3.5V. These measurement results are clearly shown in Figure 6-9 and Figure 6-10.



Figure 6-9: Transmission Response for Reconfigurable Single Polarization FSS Panel



Figure 6-10: Phase Response for Reconfigurable Single Polarization FSS Panel

# 6.4 BER Measurement for the Reconfigurable Signal Polarization FSS Panel

The setup of the measurement is shown in Figure 6-11. To test the FSS against a GSM signal being transmitted from the antenna; the free space measurement system described above was connected to a Rohde & Schwarz SMBV 100A signal generator. The signal generator was configured to transmit a standard GSM signal at a data rate of 270.833kbits/s at a carrier frequency of 1.8GHz and power level of 0dBm. The data element of the GSM burst was a continuously repeating 11 bit pseudo random binary sequence. The receiving antenna was connected to a Rohde & Schwarz FSV vector signal analyser (VSA). The VSA has the capability to demodulate the GSM signal and compute the Bit Error Rate (BER) of the received signal. The BER is computed from prior measurement of the 11 bit pseudo random sequence when the FSS is not present i.e. the received signal has a high Signal to Noise Ratio (SNR).



Figure 6-11: BER Measurement Set Up for Reconfigurable Single Polarization FSS Panel

To test the hypothesis of using a time varying FSS transmission response an AC signal generator was used to apply a square wave voltage with a DC voltage offset, such that the voltage applied across the varactor diode was of the form:

$$V_{varactor} = V_{dc} \pm V_{ac} \tag{6-1}$$

This was to ensure that the resonant frequency of the FSS was at 1.8GHz ( $V_{dc} = 3.5V$ ) and the square wave would provide transmission phase perturbations. BER measurements were carried out for a range of square wave switching frequencies and voltage amplitudes. Figure 6-12 shows a contour plot of the measured BER in percentage versus switching frequency and square wave voltage.



Figure 6-12: GSM Signal BER (%) of Reconfigurable Single Polarization FSS Panel

Figure 6-12 shows that the BER varies between 0-35% depending on the switching frequency and the applied square wave voltage. There are three particular regions of interest in Figure 6-12. The first is the low switching frequency limit, below which the BER rapidly reduces to 0%. This occurs between 700-1000Hz, depending on the amplitude of the switching waveform. Below this switching frequency the FSS will not change its phase response for all GSM bursts. The second region of interest is the high frequency limit, which is approximately 600kHz. Above this frequency the GSM signal is not impaired. The reason for this is that the received signal frequency spectrum comprises of the original baseband data plus harmonics spaced n\*fs apart, where n is an odd integer in the ideal case. For high switching frequencies these harmonics are filtered out by the GSM receiver and hence only the original, attenuated, baseband message remains. This attenuated baseband signal can be easily received, assuming it is not attenuated beyond the sensitivity of the receiver. The third region of interest is the low switching voltage amplitude limit, which controls the phase change of the FSS. This

occurs between 0.3-0.5V, which equates to a phase change of approximately  $\pm 10^{\circ}$  to  $\pm 15^{\circ}$ . The solution presented demonstrates its robustness as there are large ranges of switching frequencies and voltages, which will give a high BER.

# 6.5 Reconfigurable Dual Polarization FSS Unit Cell Design

The dual polarization FSS unit cell has been designed in Figure 6-13. The square loop has been employed as a band-stop filter, with the periodicity of the unit cell being 11mm; the width of the tracks being 0.6mm and the gaps between unit cells being 1.6 mm. The loop is fabricated on 1.6mm FR4 dielectric ( $\varepsilon_r = 4.5$ ,  $tan\delta = 0.01$ ) substrate with the gap between each unit cell being linked by a BB131 VHF variable capacitance diode (Appendix VI), used as a tuning element due to its capacitance variance being controlled from 0.7pF to 1.7pF.



Overall size: 11×11mm<sup>2</sup>, Loop thickness: 3.7mm, Line thickness: 0.6mm



Substrate: FR4, Thickness (h): 1.6mm

Figure 6-13: Front and Side View of the Reconfigurable Dual Polarization FSS Unit Cell

To estimate the performance range for the minimum and maximum values for the tuneable capacitance that links each unit cell FSS, the transmission and phase response are simulated in CST using the frequency domain, fixing the capacitance of 0.7pF and 17pF respectively which are shown in Figure 6-14 and Figure 6-15.



Figure 6-14: Transmission Response for Reconfigurable Dual Polarization FSS Unit Cell



Figure 6-15: Phase Response for Reconfigurable Dual Polarization FSS Unit Cell

From Figure 6-14 and Figure 6-15, the reconfigurable FSS can sweep the frequency response from 0.6GHz to 2.98GHz by varying the capacitance which could cover the 2G and 3G mobile phone signal frequency range. Additionally, from the data sheet (Appendix VI) for the tuning diode, when the voltage increases, the capacitance is reduced. Therefore for the operation of the transmission response will be that the desired resonant frequency of the band-stop filter will increase as the voltage is increased across the diode.

For this research the foucs will be on the 2G GSM protocol at 1.8GHz. To acheive this the capactiance of the diode has been swept in CST to find the optimum attenuation at the resonance frequency of 1.8GHz. After sweeping, the capacitance is found to be 1.92pF at the resonance frequency with the attenuation being 38.39dB which is shown in Figure 6-16. The phase response can also been seen in Figure 6-17, with the positive phase response of 72° and the negative phase response of 64°, giving an overall phase difference of 136°. Figure 6-18 shows the dual polarization reconfigurable FSS only influencing GSM signals arround the tuned selective frequency of 1.8GHz. i.e when the voltage is varied between two states the capatictance change causes a difference in phase of 136° around 1.8GHz. However in the Tetra band range (400MHz), the phase difference is very small being only 16°, which is not enough to produce a significant BER.



Figure 6-16: Transmission Response of FSS Unit Cell Tuned at 1.8GHz



Figure 6-17: Phase Response of FSS Unit Cell Tuned at 1.8GHz



Figure 6-18: Phase Response of FSS Unit Cell at varying Capacitances

# 6.6 Reconfigurable Dual Polarization FSS Panel Design

The dual-polarized reconfigurable FSS panel has been designed in CST Microwave Studio. This can be converted into a mask using AutoCAD as illustrated in Figure 6-19 (a), which can then be manufactured into a prototype FSS shown Figure 6-19 (b). The size of board is 30cm x 30cm, comprising of 26x26 individual unit cells linked by 1300 variable capacitance diodes (BB131) soldered onto the PCB board. The surrounding traces are to be utilised for the power terminals.



Figure 6-19: Reconfigurable Dual Polarization FSS Panel

A simplified version of the FSS panel structure can also be seen graphically in Figure 6-20 (a), where all red coloured unit cells connect to the positive terminal of the power supply, and the blue coloured unit cells connect to the negative terminal. The odd diagonals of red unit cells contain diodes which are connected to their neighbours on the board in reverse biased operation via connections at the top edge of the PCB board. The even column of diodes on the board are also reverse biased via connections at the bottom edge of the PCB board connected to their neighbours. The individual unit cells are connected diagonally with small metallic tabs to simplify biasing, as illustrated in Figure 6-20 (b). In this configuration the FSS operates when the incident electric field is two different polarizations (parallel or perpendicular) to the diode orientation in order to demonstrate a polarization insensitivity of the FSS panel.



(a) Bias Schematic (b) Fabricated Board with Diodes Figure 6-20: The structure of the FSS Panel

# 6.7 Reconfigurable Dual Polarization FSS System Measurement

The measurement for the dual polarization FSS panel is to validate its simulation results. The setup of the process is the same as the single polarization FSS panel shown in Figure 6-8. The difference is that after measuring the transmission response for one polarization, the horn antennas were kept stationary while the FSS was rotated 90°, where the initial position of the FSS panel was marked on the metal plate as a reference.

On the initial position of the FSS panel, the data for transmission and phase response were shown in Table 6-2.

Voltage (V)	Transmission Response (dB)	Phase (Degree)	Voltage (V)	Transmission Response (dB)	Phase (Degree)	Voltage (V)	Transmission Response (dB)	Phase (Degree)
0.5	-21	130	10.5	-27	-105	20.5	-20	-123
1	-21	132	11	-29	-91	21	-20	-120
1.5	-21	135	11.5	-31	-79	21.5	-19	-118
2	-21	137	12	-33	-67	22	-19	-116
2.5	-21	139	12.5	-38	-52	22.5	-19	-114
3	-22	142	13	-51	-29	23	-19	-113
3.5	-22	145	13.5	-44	136	23.5	-19	-112
4	-22	148	14	-35	153	24	-19	-110
4.5	-22	152	14.5	-31	163	24.5	-18	-109
5	-23	155	15	-28	173	25	-18	-108
5.5	-23	160	15.5	-26	-176	25.5	-18	-107
6	-23	166	16	-25	-168	26	-18	-106
6.5	-23	172	16.5	-24	-161	26.5	-18	-106
7	-23	179	17	-23	-153	27	-18	-105
7.5	-24	-172	17.5	-22	-148	27.5	-18	-104
8	-24	-162	18	-22	-142	28	-17	-103
8.5	-24	-151	18.5	-21	-137	28.5	-17	-102
9	-25	-141	19	-21	-132	29	-17	-102
9.5	-25	-130	19.5	-20	-129	29.5	-17	-101
10	-26	-117	20	-20	-125	30	-17	-101

Table 6-2: The Transmission and Phase Response for the FSS against Voltage at initial position

From Table 6-2, the DC voltage has been varied from 0.5V to 30V which provided attenuation variation between 17dB to 51dB and a phase variation between  $-172^{\circ}$  to  $+173^{\circ}$ , These measurement results are clearly shown in Figure 6-21 and Figure 6-22.


Figure 6-21: Transmission Response for Initial Position of the FSS Panel



Figure 6-22: Phase Response for Initial Position of the FSS Panel

The Figure 6-23 and Figure 6-24 show the transmission response and phase response against frequency from 11V to 14V. From these two figures, at 1.8GHz the maximum attenuation was measured at 51.4dB and a phase variation between  $+3^{\circ}$  to  $-150^{\circ}$  at 13V.



Figure 6-23: Transmission Response against Frequencies at Initial Position of FSS Panel



Figure 6-24: Phase Response against Frequencies at Initial Position of FSS Panel

After the initial position of the FSS panel has been measured, the FSS was carefully rotated 90°. All measurement procedures were repeated. The data for transmission and phase response are shown in Table 6-3.

Voltage (V)	Transmission Response (dB)	Phase (Degree)	Voltage (V)	Transmission Response (dB)	Phase (Degree)	Voltage (V)	Transmission Response (dB)	Phase (Degree)
0.5	-20	130	10.5	-26	-80	20.5	-20	-126
1	-21	133	11	-26	-62	21	-20	-124
1.5	-21	135	11.5	-27	-44	21.5	-20	-121
2	-21	138	12	-28	-25	22	-19	-119
2.5	-21	141	12.5	-30	-1	22.5	-19	-117
3	-22	143	13	-31	26	23	-19	-115
3.5	-22	146	13.5	-32	56	23.5	-19	-114
4	-22	150	14	-31	89	24	-19	-113
4.5	-22	153	14.5	-30	118	24.5	-18	-111
5	-22	158	15	-28	140	25	-18	-110
5.5	-23	162	15.5	-26	157	25.5	-18	-109
6	-23	169	16	-25	171	26	-18	-108
6.5	-23	176	16.5	-24	-175	26.5	-18	-107
7	-23	-174	17	-23	-165	27	-18	-106
7.5	-23	-164	17.5	-22	-156	27.5	-18	-105
8	-23	-151	18	-22	-150	28	-17	-104
8.5	-24	-139	18.5	-21	-143	28.5	-17	-104
9	-24	-128	19	-21	-138	29	-17	-103
9.5	-24	-111	19.5	-21	-133	29.5	-17	-102
10	-25	-97	20	-20	-130	30	-17	-102

Table 6-3: The Transmission and Phase Response for the FSS against Voltage after rotated 90°

In Table 6-3, the DC voltage has been varied from 0.5V to 30V which provided attenuation variation between 17 to 32dB and a phase variation between  $-174^{\circ}$  to  $171^{\circ}$ . These measurement results are clearly shown in Figure 6-25 and Figure 6-26.





Figure 6-25: The Transmission Response of FSS Panel Rotate 90°



Figure 6-27 and Figure 6-28 show the transmission response and phase response against frequency from 11V to 14V. From these two figures, at 1.74GHz the maximum attenuation was measured at 43dB and a phase variation between  $+38^{\circ}$  to  $+174^{\circ}$  at 13V.



Figure 6-27: Transmission Response against Frequencies after FSS Panel Rotated 90°



Figure 6-28: Phase Response against Frequencies after FSS Panel Rotated 90°

So from the results above in Figure 6-23, the simulation results in Figure 6-16 are matched at 1.8GHz when a voltage of 13V is applied. Also the measurement results of the initial position of the FSS panel is very similar as the measurement results of the FSS panel after turning 90° but has a slight frequency shift to the left at the resonant frequency response.

## 6.8 BER Measurement for the Reconfigurable Dual Polarization FSS

The setup of the BER measurement for the reconfigurable dual polarization FSS panel is the same as the single polarization FSS panel shown in Figure 6-11. To test the FSS against a GSM signal being transmitted from the antenna, the free space measurement system is used as described above, connected to a Rohde & Schwarz SMBV 100A signal generator. The data element of the GSM burst was a continuously repeating 11 bit pseudo random binary sequence. The receiving antenna was connected to a Rohde & Schwarz FSV vector signal analyser (VSA). The VSA has the capability to demodulate the GSM signal and compute the Bit Error Rate (BER) of the received signal. The BER is computed from prior measurement of the 11 bit pseudo random sequence when the FSS if not present i.e. the received signal has a high Signal to Noise Ratio (SNR). BER measurements were initially carried out when the FSS was placed between the transmitter and receiver antennas, and a DC bias voltage of 13 Volts was applied across the varactor diodes to provide maximum attenuation. The received signal power in this case was approximately -60dBm as shown in Figure 6-29. This is also above the sensitivity limit of the VSA, therefore in initial measurement the BER was zero, as expected.



#### Figure 6-29: Received Signal power against Frequencies

To measure the BER of the reconfigurable dual polarization FSS panel, the resonant frequency of the FSS is kept at 1.8GHz using the DC voltage offset ( $V_{dc}$ ) of 13V being applied. A square wave voltage ( $V_{ac}$ ) is then applied from an AC signal generator at different ranges of switching frequencies ( $f_s$ ).

Figure 6-30 and Figure 6-31 shows a contour plot of the measured BER in percentage for  $0^{\circ}$  and  $90^{\circ}$  rotation of the FSS.



Figure 6-30: GSM Signal BER (%) of Reconfigurable Dual Polarization FSS Panel



Figure 6-31: GSM Signal BER (%) of Reconfigurable Dual Polarization FSS Panel rotated 90°

From Figure 6-30 and Figure 6-31, when the switching frequency and square wave voltage changes, the BER can increase up to 36%. The results compare with the single polarization switching FSS, with the results following the same trend. Firstly, they have similar low switching frequency limits which are between 700-1000Hz and high frequency limits around 600kHz. If the BER is observed below or above these frequency limits the BER rapidly reduces to 0%, meaning the GSM signal is not impaired and the correct mobile phone signal will be received. The solution presented demonstrates its robustness as there are large ranges of switching frequencies and voltages, which will give a high level of BER, which can make sure the mobile phones do not receive the correct signal. This solution has better performance compared with passive FSS, as it is not limited to the strength of the signal received from the base station.

# 6.9 Frequency Spectrum Measurements for the Reconfigurable Dual Polarization FSS

Shown in Figure 6-32 to Figure 6-36 is the effects on the frequency spectrum as the reconfiguration dual polarization FSS is switch at different frequencies. These measurements were obtained using a fixed offset of 13 volts DC and a square wave switched signal of 1 volt peak-to-peak. To observe a more stable spectrum, the GSM data selected was set at all ones, with a sweep time of 1s being set on all measurements measured by a vector signal analyser as previously shown in Figure 6-11. Figure 6-32 shows the FSS at its normal passive state where not external voltage is applied, illustrating only the received signal at 1.8 GHz.



Figure 6-32 Frequency Spectum for Reconfigurable Dual Plarization FSS – No Switching

Figure 6-33 shows when the FSS is actively switched at 2.71 MHz causing the signal to shift from the centre frequencies into the sidebands at equally space apart harmonics. As the harmonics are not within the original spectrum a bit error rate of zero can still be obtained.



Figure 6-33 Frequency Spectum for Reconfigurable Dual Plarization FSS – Switching At 2.71 MHz

Figure 6-34 again shows when the FSS is actively switch at a lower rate of 1 MHz causing even more harmonics equally space apart around the centre frequency of 1.8 GHz.



As the harmonics are not within the original spectrum a bit error rate of zero can still be obtained.

Figure 6-34 Frequency Spectum for Reconfigurable Dual Plarization FSS – Switching At 1 MHz

Figure 6-35 show when the FSS is switched at a much lower frequency of 271 kHz, causing the equally spaced apart harmonics to interfere with the original frequency spectrum. Due to this reasons a bit error rate of 44.3% can be observed at this switching frequency.



Figure 6-35 Frequency Spectum for Reconfigurable Dual Plarization FSS – Switching At 271 kHz

Figure 6-36 shows the final measured switching frequency of 135.5 kHz. Again as observed at the switching frequency of 271 kHz the equally spaced apart harmonics are interfering with the original centre frequencies at 1.8 GHz causing a bit error rate of 44.2% being measured.



Figure 6-36 Frequency Spectum for Reconfigurable Dual Plarization FSS – Switching At 135.5 kHz

The above measurements all follow the same observations that were simulated in Figure 5-5 to Figure 5-7, where the sideband harmonics interfere causing bit errors when being too close to the original centre frequency spectrum.

# 6.10 Summary

Two reconfigurable switching FSS panels were manufactured for measurement. One for single polarization and the other dual polarization, 2-D surface plots of their measurements all follow the same trend as the simulation results obtained in MATLAB.

# CHAPTER 7 DIFFRACTION FROM FREQUENCY SELECTIVE SURFACES FOR SECURE BUILDING APPLICATION

A Frequency Selective Surface (FSS) can be used to control mobile phone signal propagation both in and out of buildings. When an FSS is to be designed to be attached to a building surface, such as a window, there are two main aspects which affect its performance. The common research interest is to design a FSS that can alter the specular attenuation for a range of angles and polarizations. For secure buildings applications the level of attenuation needed to stop signals propagating into a room requires the need to investigate the level of diffraction scattering from the FSS. This chapter focuses on the diffraction issues associated with a FSS design when used for secure building applications.

In order to design a FSS to block mobile phone frequency, an assessment needs to be made on the power levels expected in a room or building that is required to be secure. This can be carried out using various modelling techniques. Depending on the level of attenuation needed by the FSS solution it may be required to assess not only the specular response but also non-specular diffraction to determine its impact on system performance. Non-specular scattering will be of importance for Non Line of Sight when very high attenuation levels are required.

# 7.1 FSS Non-Specular Scattering Scenario

A scenario is considered in which an FSS is placed across a window of a building to reduce the power between a Base Transceiver Station (BTS) and a mobile device as shown in Figure 7-1, which CST model is illustrated in Figure 7-2. The received signal will comprise of the direct path and the diffraction from the FSS/metal interface. It is assumed that the rest of the room consists of metallic surfaces and is perfectly isolating. The simulations were carried out using the time domain solver within CST Microwave Studio.



Figure 7-1: The Signal Received by Base Station



Figure 7-2: Illustration of an FSS in a Secure Room

In order to simulate the diffraction from the FSS/metal interfaces, a 3D simulated wall surface model was produced, which is illustrated in Figure 7-4. The size of the wall is 2m x 2m which has an aperture 0.5m x 0.5m in the middle, with the FSS panel containing 100 FSS unit cells being attached to this aperture. Each FSS simulation comprises of a square metallic loop with a unit cell periodicity of 50mm, loop size of 46.5mm and the

width of the metallic loop being 4.25mm and tuned to operate at 1.8GHz, the attenuation is 54dB for normal incidence in Figure 7-3.



(a) Unit Cell

FSS Type	P(mm)	G(mm)	W(mm)
Single Square Loop FSS	50	1.75	4.25



(b) Dimensions

(c) Simulation Transmission Response Figure 7-3: The Transmission Response for the Unit Cell

A simulated 1V/m plane wave illuminates the structure at varying angles from the surface of the FSS with the E-field parallel to the FSS/metal interface. The scattered E-field is

monitored at a fixed distance of 1.2m from the metal wall. To assess the far field scattering of the structure diffraction from the wall surface was removed by replacing the FSS with a continuous PEC sheet. This flat PEC sheet represents a perfect reflector, where the entire of the incident signal would be reflected. For fair comparison, this size of the PEC sheet needs to have the exact same dimensions as a metal wall containing an FSS panel. The scattering radiation simulated from the far field scenarios with and without the FSS were subtracted to provide the scattering from the FSS region only.



Figure 7-4: 3-D Wall Surface

## 7.2 FSS Non-Specular Scattering Radiation Pattern Analysis

A scenario is considered in which an FSS is placed across a window of a building to reduce the power between a Base Transceiver Station (BTS) and a mobile device as illustrated in Figure 7-1. The scattered E-field is monitored at a fixed distance of 1.2m around metal wall by a far field monitor simulated in CST software.

Scattering pattern results need to be employed to analyse the diffraction scattering from different incident angles. Figure 7-5 (a) is an illustration for a plane wave with incident angle of  $20^{\circ}$  from the vertical wall surface. Figure 7-5 (b) is the 3-D simulated result,

which shows the E-field of the wall surface when subject to a 1V/m plane wave for all forward and back scattering angles.



Figure 7-5: 20° Incident Angle from the Wall Surface with 3-D Simulation Result

A field monitor has been used to monitor the E-field in the far-field from 0 to 3GHz. The plot in Figure 7-5 (b) represents the scattered field at 1.8GHz. This research focuses on the scattering field inside a building, ranging from -180° to 0° (forward scattering angles). Additionally, the results are normalised to the scattered E-Field from a PEC surface of the same dimensions in the specular direction which equates to a reflection coefficient of -1. This research focuses on observing diffraction scattering from varying incident angles, using four different incident angles (20°, 40°, 60°, 80°) as examples. The radiation patterns for the PEC sheet at different angles have been simulated using CST which are shown in Figure 7-6, where the main lobe magnitudes are 15dBm/V at 20°, 22dBm/V at 40°, 25dBm/V at 60° and 26dBm/V at 80°. When the results are normalised, they need to be subtracted using different peak magnitudes of the main beam depending on their simulated incident angle.



(a) Incident Angle at  $20^{\circ}$ 





(c) Incident Angle at 60°
(d) Incident Angle at 80°
Figure 7-6: Radiation Pattern Flat PEC Sheet at Different Incident Angles

Figure 7-7 to Figure 7-10 show the normalised scattered field Cartesian plot results for different incidence angles ranging from 20° to 80° over the whole angular range of interest at 1.8GHz for the scatter field. The scattering with, or without, a FSS on the wall surface were subtracted in the far field to provide the scattering from the FSS region only. The results show the effective scattering field of the FSS to a 1V/m plane wave for all

forward scattering angles. As expected there are peaks in the response at the specular angles, which are a combination of the standard transmission response plus the diffraction from the FSS edges.



Figure 7-7: Incident Angle at 20° for the scatter field



Figure 7-8: Incident Angle at 40° for the scatter field



Figure 7-9: Incident Angle at 60° for the scatter field



#### Figure 7-10: Incident Angle at 80° for the scatter field

From Figure 7-7 to Figure 7-10, the peaks can be found at around -160°, -140°, -120° and -100° for incidence angles of 20°, 40°, 60° and 80° respectively. The small spikes in the data near the forward scattering direction are due to minor variations of the mesh within CST. This is particularly important when carrying out the subtraction of the PEC surface so that the scattering of the FSS region alone can be carried out.



Figure 7-11: Comparison of Incident Angle at 20° and 80°

Figure 7-11 compares the scattered field results for  $20^{\circ}$  and  $80^{\circ}$  with the results illustrating that for the non-specular angles the diffraction from the FSS is an important factor. *Figure* 7-12 shows the transmission response for the FSS unit cell at different incident angles.



Figure 7-12: The Transmission Responses of the Large Unit Cell

The specular scattering of the FSS unit cell at 1.8GHz have been listed in Table 7-1. Measurements were taken from the internal and external areas of the Mappin building at the University of Sheffield, where the values obtained showed that a secure room would require levels of attenuation over 60dB in order to prevent wireless communication. This table indicated that the normalised scattered field is between -37dB to -51dB, which would potentially still allow a mobile phone inside the secure building to receive the transmitted base station signals.

Incidence	Specular Secttoring	Normalised Scattered Field (dB)						
(Degrees)	(dB)	-90 •	-70 •	-50°	-20 •			
20°	-22	-37	-36	-38	-41			
40°	-22	-38	-38	-40	-43			
60°	-27	-41	-44	-47	-51			
80°	-41	-32	-42	-46	-51			

Table 7-1: Specular Scattering and Normalised Scattered Field

This can be further expanded by comparing the difference in forward scattering in two different scenarios. The first scenario would be the metal wall with a FSS on the window aperture as seen above, and second would be the metal wall with an window aperture with the FSS removed. The comparisons will be for the far field at different specular angles. Incident angles of 60° and 80° have been simulated as examples and results are illustrated in Figure 7-13 and Figure 7-14. For fair comparison, the aperture has been created with the same size as the FSS panel. The results show the specular performance of the FSS being unaltered, as expected; but there is a reduction for the metal wall with FSS present where the non-specular scattering can introduced an additonal 5dB in field strength.



Figure 7-13: Comparison Metal Wall with FSS and With Aperture Cases at Specular Angle at 60°



Figure 7-14: Comparison Metal Wall with FSS and With Aperture Cases at Specular Angle at 80°

In order to reduce the non-specular scattering, the FSS unit cell design was altered, as shown in Figure 7-15. The FSS is now half the size of the original one, but the normal incidence specular performance of the small FSS still operates at 1.8GHz as shown in Figure 7-16.



FSS Type	P(mm)	G(mm)	W(mm)
Single Square Loop FSS	25	0.5	1.26

Figure 7-15: Small Unit Cell



Figure 7-16: Transmission Response for a Smaller Unit Cell

Figure 7-17 to Figure 7-20 compare the forward scattering performance between the redesigned 25mm and previous 50mm designed unit cell, over different incident angles. It can also be seen that the non-specular scattering of the smaller designed unit cells is smaller than the previous designed unit cell in all incident angle scenarios. This means

the smaller element redesigned FSS panel has less leakage compared with the larger previous FSS panel place over the window aperture.



Figure 7-17: Comparison of 25mm and 50mm Unit Cell at incident angle of 20°



Figure 7-18: Comparison of 25mm and 50mm Unit Cell at incident angle of 40°



Figure 7-19: Comparison of 25mm and 50mm Unit Cell at incident angle of 60°



Figure 7-20: Comparison of 25mm and 50mm Unit Cell at incident angle of 80°

Figure 7-21 shows the transmission response for the smaller unit cell design at different incident angles.



Figure 7-21: Transmission Responses for the Small Unit Cell

Table 7-2 summarises the specular scattering and normalised scattered field at 1.8GHz, where it needs to be kept in mind that a secure room requires at least 60dB of attenuation to stop wireless communication. As previously obtained to compare with, the normalised scattered field is between -37dB to -51dB for the large unit cell design. The normalised scattered field for the small unit cell design ranges between -50dB to -82dB. Although the performance is improved with less leakage from the FSS unit cell design, a mobile phone contained within a secure building, still may pick up the signals from the base station.

Incidence angles (Degrees)	Specular Scattering (dB) for Small Unit	Small Unit Cell Normalised Scattered Field (dB)				Large Unit Cell Normalised Scattered Field (dB)			
	cell	-90 •	-70 •	-50	-20 •	-90 •	-70 •	-50°	-20 •
20°	-18	-71	-64	-59	-55	-37	-36	-38	-41
40°	-18	-56	-59	-59	-55	-38	-38	-40	-43
60°	-30	-50	-53	-82	-56	-41	-44	-47	-51
80°	-41	-40	-49	-61	-60	-32	-42	-46	-51

Table 7-2: Specular Scattering and Normalised Scattered Field of Small and Large Unit Cell

In order to reduce the non-specular scattering issues observed, other improved FSS designs should be considered. This research will explore two design methods that could achieve this: First a FSS unit cell the same size as the original design, which has been rotated by  $45^{\circ}$ , and the second metal teeth are added to the original design around the window part that interfaces with the FSS.

The first rotated FSS unit cell as shown in Figure 7-22 keeping its transmission response operating at 1.8GHz as simulated in Figure 7-23.



FSS Type	P(mm)	G(mm)	W(mm)
Single Square Loop FSS	50	3.5	4.25

Figure 7-22: Rotate Unit Cell 45°



Figure 7-23: Transmission Response for Rotate FSS 45°

Figure 7-24 to *Figure 7-27*, compare the scattering performance of the original unit cell and its rotated counterpart at  $45^{\circ}$  over different incident angles. From the simulation results, when the incident angle is smaller, the reduction of scattering appears more signification, for example the unit cells that has been rotated through  $45^{\circ}$  will become a rhombus. The plane wave would "see" the sharp point of the rhombus. If the angle is further increased to  $90^{\circ}$  (normal incidence), the plane wave would "see" the whole rhombus as a flat surface.



Figure 7-24: Comparison of Original and Rotated Unit Cell at Incident Angle of 20°



Figure 7-25: Comparison of Original and Rotated Unit Cell at Incident Angle of 40°



Figure 7-26: Comparison of Original and Rotated Unit Cell at Incident Angle of 60°



Figure 7-27: Comparison of Original and Rotated Unit Cell at Incident Angle of 80°

Figure 7-28 shows the transmission response for the rotated unit cell at different incident angles.



Figure 7-28: The Transmission Response for the Rotate FSS Panel

Table 7-3 compares the previous large panel FSS design with the new rotated panel for the specular scattering at 1.8GHz and normalised scattered field. It can be clearly seen that the rotated design has significantly improved the diffraction scattering ranging between -49dB to -76dB for the normalised scattered field. Although scattered fields are reduced, some values for the receiver angle (Theta) are still above the 60dB attenuation level to stop wireless communication.

Incidence angles	Specular Scattering	Norma Re	alised Sc otated U	attered 1 nit Cell (	Field for (dB)	Normalised Scattered Field for Large Unit Cell (dB)			
(Degrees)	(dB) for Rotate Unit Cell	-90 •	-70 •	-50 •	-20 •	-90 •	-70 •	-50 •	-20 •
<b>20</b> °	-21	-75	-76	-52	-52	-36	-35	-37	-40
<b>40</b> °	-22	-62	-65	-51	-53	-38	-38	-40	-43
60°	-29	-63	-69	-53	-53	-41	-44	-47	-51
80°	-47	-49	-59	-56	-54	-32	-42	-46	-51

Table 7-3: Specular Scattering and Normalised Scattered Field of Rotated and Large Unit Cell FSS

The second method of adding metal teeth surrounding the window part that interfaces with the FSS will also help to reduce the scattering. This is shown in Figure 7-29, with the height of each metal tooth being 125mm and the FSS panel attached to the window part still operating at 1.8GHz.



D1=2000mmD2=500mmH=125mmFigure 7-29: FSS Panel with Metal Teeth attached to a Metal Wall

The simulation results in Figure 7-30 to Figure 7-33 are the comparison of the FSS panel being attached to the window part with and without the metal teeth surrounding the interfacing window part at different incident angles. The scattered field levels are recorded in in Table 7-4 and they clearly show that the metal teeth surrounding the FSS will reduce the non-specular scattering.



Figure 7-30: Comparison of FSS Panel, with and without Metal Teeth at Incident Angle of 20°



Figure 7-31: Comparison of FSS Panel, with and without Metal Teeth at Incident Angle of 40°



Figure 7-32: Comparison of FSS Panel, with and without Metal Teeth at Incident Angle of 60°



Figure 7-33: Comparison of FSS Panel, with and without Metal Teeth at Incident Angle of 80°

Incidence angles (Degrees)	Norm M	alised Sc etal Tee	attered 1 th Panel	Field for (dB)	Normalised Scattered Fie for Large Unit Cell Pane (dB)			
	-90 •	-70 •	-50 •	-20 •	-90 •	-70 •	-50 •	-20 •
20°	-46	-46	-65	-51	-36	-35	-37	-40
40°	-41	-44	-47	-45	-38	-38	-40	-43
60°	-42	-50	-64	-59	-41	-44	-47	-51
80°	-41	-42	-56	-56	-32	-42	-46	-51

 Table 7-4: Specular Scattering and Normalised Scattered Field of Metal Teeth and Large Unit Cell

 Panel

## 7.3 Summary

This chapter illustrates the importance of FSS diffraction scattering for secure building applications in high signal strength areas. Measured results of a typical building show that attenuation levels of FSS may need to be greater than 60dB, in order to stop mobile communications. In such cases the methods for reducing the non-specular scattering mechanisms as well as traditional FSS design should be considered. For this reason, a 3D simulated wall surface model was produced in CST modelling software to observe a FSS non-specular scattering scenario. The scattered field of the wall surface is observed from different incident angles ranging from 20° to 80° by using radiation patterns in the format of a Cartesian plot. It has also been shown that suitable FSS design concepts are capable of reducing the non-specular scattering. e.g. smaller unit cells, rotated unit cells and metal teeth added to the perimeter of the FSS panel.

# CHAPTER 8 CONCLUSION

The objective of this research is to investigate the use of a FSS, for a special building application, e.g. for a prison, where a FSS could be used to block three mobile phone frequency bands GSM800 (890MHz - 960MHz), GSM1800 (1710MHz - 1875MHz) and UMTS (1920MHz - 2170MHz), but still allow TETRA (380MHz - 420MHz) which enables emergency calls to pass though.

Different types of classical passive FSS structures which could be used on buildings have been researched, where attenuation is normally between -30dB to -60dB depending on their shape and material. Current research shows that mobile phones can operate with received power levels as low as -120dBm. So to asses power levels to secure a build in different locations, a total of 249 prisons in the UK where analysed in order to work out the 2G cellular network signal quality. After analysing the power levels of different level security prisons from mobile operator's websites; it can be seen that a large proportion of prisons have a rated excellent signal quality and so a field test would need to be conducted in order to find out an average level of attenuation for this signal quality. These measurements were conducted using a portable spectrum analyser for both inside and outside of the Sir Frederick Mappin Building at the University of Sheffield. This location also had a rating of an excellent signal quality for fair comparison. Electric field strength measurements were carried out at 900MHz and 1800MHz for the 2G mobile networks. So from these obtained results, the possibility for a secured room would require at least an attenuation above 60dB in order to filter out the required signal bands in an excellent signal quality area.

Passive FSS are limited to attenuate a mobile phone signal to the required levels from the field tests. For this reason, innovation of a reconfigurable switching FSS structure has been designed and tested, which assumes the walls of the building have been perfectly shielded, and the signal can only propagate where the FSS is applied on a building aperture such as window. Also this aperture is assumed to be large enough with respect to the wavelength of the incoming signal such that diffraction effects can be ignored.

Two reconfigurable FSS panel have has been designed, one is a reconfigurable single polarization FSS system, and another is a reconfigurable dual polarization FSS system. These two systems both use varactor diodes embedded into the FSS structure which are controlled by an external bias voltage. This change in voltage can rapidly change the

complex transmission response causing corruption to a received mobile phone signal. This means that the receiver inside the building cannot determine the data which was transmitted from outside the building from a base station.

Initially, these reconfigurable systems have been simulated in CST, where the capacitance of the diode can be controlled by an external bias voltage. The reconfigurable single polarization design uses diode (BB857), with capacitance varied from 0.45pF to 7.2pF. This allows for a reconfigurable single polarization FSS swept frequency response from 0.9GHz to 3.1GHz. The reconfigurable dual polarization FSS uses diode (BB131), with capacitance varied in a different range of 0.7pF to 1.7pF. This allowed for a reconfigurable dual polarization FSS swept frequency response from 0.6GHz to 2.98GHz by varying the capacitance. If the voltage is increased across the diode, the desired resonant frequency will be also increased. Both swept frequency ranges would be able cover the 2G and 3G mobile phone signal frequency ranges.

Further to this, the switching FSS design have been tested against the GSM protocol which has been simulated by coding in MATLAB. The design of this GSM framework is introduced in Chapter 4. Once GSM protocol is understood, the MATLAB simulation was configured to transmit a standard GSM signal at a data rate of 270.833kbits/s. The modulation scheme used is GMSK, with a GSM frame being split into eight bursts. As a frame time of 4.6ms is used a burst time of 0.577ms is calculated, with a total bit duration of 3.692 µs.

Twelve elements of the GSM system are used in this research which are listed as follows: speech signal, convolutional coding, interleaving, differential encoding, GSMK modulation, channel, low-pass filtering, GSMK demodulation, MLSE, Differential decoding, de-interleaving and convolutional decoding. The function of each element has been introduced and comparisons of simulation results with results done by the previous work are performed.

To simulate results a random data stream is switched over a GSM channel, for a unit transmission coefficient magnitude of the FSS. The study focused on observations of varying phase. The bandwidth of the filter may vary depending on the receiver topology which is very important as it impacts the overall BER. The frequency spectrum of a switched GSM channel shows this phase switching technique shifts the energy at the carrier frequency to the sidebands, with these sidebands being odd multiples of the switching frequency. The frequency spectrum near the carrier (0Hz) is also an
attenuated version of the original baseband spectrum. e.g. When the switching frequency is 2.7MHz, the spectrum contains the original baseband data plus harmonics spaced n\*fs apart, where n is an odd integer and the first harmonics being at 2.7 MHz, second at 8.1MHz and so on. If the receiver simulated uses a filter bandwidth of 270 kHz, the in-band signal is retained when filtered by the receiver. This allows for the attenuated baseband signal to be recovered, giving a BER of 0%. If the switching frequency is changed to 135 kHz, the low frequency switching causes the sidebands to be retained when filtered by the receiver to filter out the unwanted sideband energy, and therefore a BER of 42% is obtained.

2-D surface plots of the BER generated by MATLAB show the averaged BER for all GSM signals transmitted through the surface. Results are achieved by using 100 random seeds being switched in the same way using different phase values. Significant BER can be achieved over a large range of switching frequency and transmission phases. e.g. the signal impairment can be seen for switching frequencies as low as 1kHz and a high frequency cut-off being approximately 270 kHz when using a receiver filter with cutoff of 270 kHz.

The research continues by constructing a reconfigurable FSS to validate the MATLAB GSM protocol simulations. This is achieved by using a square wave being set at the required external bias voltage to imitate the phase switching performed in MATLAB. BER results seen varied between 0 and 35% depending on the applied voltage and the frequency in which the square wave is generated. These results closely matched the simulated results.

Additionally, the level of diffraction scattering from the edge of an FSS panel on the window aperture has been investigated. Non-specular scattering will be important for Non Line of Site, especially in high signal strength areas. A scenario has been created which assumed that the room is made of metal and is isolating, and that the mobile phone signal can only transmit through the window. To assess the far field scattering of the structure, the scattering radiation simulated from the far field scenarios of with and without the FSS were subtracted to provide the scattering from the FSS region only.

As previously discovered, a secure room required attenuation levels of over 60dB to prevent wireless communication. After comparison of the incident angle at different angles, the normalized scattered field of the example large unit cell was between -37dB to -51dB, causing a mobile phone to still pick up signals inside a secure building from

the base station. Methods to reduce non-specular scattering where investigated by creating three different types of FSS panels. The first design simulated was to alter the size of FSS unit cell to half the size of the original. Next a unit cell design rotated by 45° was simulated. Finally a design in which metal teeth were added to perimeter of the simulated FSS panel. All three designs kept the unit cell transmission response at 1.8GHz at normal incidence, with all having a reduction in the non-specular scattering help prevent signal leakage in the window to the aperture.

## CHAPTER 9 FUTURE WORK

#### 9.1 Smart FSS design

In this research reconfigurable FSS has been designed and simulated in the CST simulation software, but has been modelled using cost effective materials which don't have transparent properties. Transparent reconfigurable FSS designs will need to be considered for use in window apertures to let the sunlight propagate through the surface.

Future work will also investigate multiband reconfigurable FSS to provide operation over a number of bands in present and future spectral usage. Techniques for enhancing and impairing wireless signals through time varying FSS performance will be investigated.

Additionally, future work will address issues such as FSS maintenance, durability and cost, with respect to the proposed lifetime of the technology.

#### 9.2 3D building simulation

Realistic 3D models of scenarios such as offices, corridors, cupboards etc. will need to be implemented in commercial electromagnetic packages (CST, FEKO) to estimate the performance that a FSS designed in previous research work could deliver.

A combination of full field modelling and complex signal processing will be employed to evaluate and optimise the performance.

#### **9.3** Verifying theoretical results with measurement results

To obtain reliable results, measurements will need to be carried out to validate the simulation results. A representative "building", which could be a scaled version of adjoining rooms or by modifying existing rooms, needs to be constructed. State of the art communications equipment will be used to transmit and receive signals in the representative building to assess the FSS performance. The communications group has manufactured a representative office space at its Buxton site, which will be used on this future project.

#### 9.4 Measurement of different concrete materials

In more recent building structure designs, new composite concrete materials are to be used, which includes varying the different percentage of steel fibres contained within the concrete to improve strength. For future study, when a suitable FSS has been designed, the effect of this concrete material as a background also needs to be considered. The total attenuation can be measured by attaching the FSS in front of the concrete.

## 9.5 Investigate Diffraction Scattering from FSS Panel with Missing Elements

Traditional methods to manufacture a FSS involve chemically etching a metal film to form the required pattern. This can be expensive, so cheaper fabrication would be required for building application, such as inkjet technology; during this printing process, some elements may be missing from the FSS panel, and so in this case, the diffraction scattering needs to be investigated to calculate how much power will leak inside a room.

## 9.6 Reconfigurable Switching FSS Switch over Different Modulation Schemes

In this research, the modulation scheme GSMK has been employed for GSM. The concept has been to corrupt the mobile phone signal by phase switching. This method could be applied to other phase modulation schemes, such as: Quadrature Phase Shift Keying, for future research studies. The simulation and measurement for different phase modulation schemes will be investigated.

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#### **Prison Name** Address Post Code Category **OP-A** OP-B OP-C OP-D Southall Street, Strangeways, HMP MANCHESTER M60 9AH Α 5 5 2 5 MANCHESTER Higher Lane, Fazakerley, HMP ALTCOURSE L9 7LH 5 5 2 5 A LIVERPOOL Off North Bridge, Marshgate, HMP/YOI DONCASTER, South DN5 8UX 5 5 2 5 A DONCASTER Yorkshire Mauchline Road, HMP BOWHOUSE Bowhouse, KILMARNOCK, 3 KA1 5AA Α 5 1 5 East Ayrshire 17, Old Road, HMP & IDC Upper Ballinderry, BT28 2PT A 5 4 2 5 MAGHABERRY LISBURN, Co.Antrim HMP Shotts Newmill & Canthill Road, HMP SHOTTS NIC ML7 4LE 3 4 1 4 A B SHOTTS, North Lanarkshire South Road, PETERHEAD, HMP PETERHEAD AB42 2YY A B 5 4 1 5 Aberdeenshire King O'Muir Road, HMP GLENOCHIL FK10 3AD 5 Tullibody, ALLOA, ABC 5 5 1 Clackmannanshire HMP/YOI Stradishall, NEWMARKET, CB89YG ABCD 5 2 2 3 EDMUNDS HILL Suffolk 3, Edinburgh Road, A C HMP PERTH PERTH. PH2 8AT 5 5 2 5 Perthshire & Kinross 55, Parkhurst Road, Parkhurst, NEWPORT, PO30 5RS 2 HMP ALBANY В 4 5 5 Isle of Wight 2 Ribbleton Lane, HMP PRESTON PRESTON, PR1 5AB В 5 2 5 5 Lancashire The Terrace, Upper HSH BROADMOOR Broadmoor Road, RG45 7EG В 5 5 2 5 CROWTHORNE. HOSPITAL Berkshire Werrington, STOKE-ON-HMYOI TRENT, ST9 0DX В 5 5 2 5 WERRINGTON Staffordshire Bierton Road, HMYOI AYLESBURY, HP20 1EH В 5 5 2 5 AYLESBURY Bucks St. Loyes Street, HMP BEDFORD MK40 1HG 2 5 В 5 5 BEDFORD Winson Green Road, HMP BIRMINGHAM B18 4AS В 5 4 2 5 BIRMINGHAM HMP Hewell Lane, REDDITCH, B97 6QS В 5 4 1 5 BLAKENHURST Worcestershire Lakeside Rise, Blundeston, HMP BLUNDESTON NR32 5BG В 5 5 1 4 LOWESTOFT, Suffolk

## **APPENDIX I: PRISON LIST**

HMP BRISTOL	19, Cambridge Road, Horfield, BRISTOL	BS7 8PS	В	5	5	2	5
HMP BRIXTON	PO Box 369, Jebb Avenue, LONDON	SW2 5XF	В	5	5	2	5
HMP BRONZEFIELD	Woodthorpe Road, Ashford, STAINES London	TW15 3JZ	В	5	5	2	5
HMP BULLINGDON	PO Box 50, Patrick Haugh Road, Arncott, Nr. BICESTER, Oxon	OX6 0PZ	В	5	3	2	5
HMP/RC CARDIFF	Knox Road, CARDIFF	CF24 0UG	В	5	5	2	5
HMP/YOI CHELMSFORD	200, Springfield Road, CHELMSFORD, Essex	CM2 6LQ	В	5	5	2	5
HMP DOVEGATE	off Moreton Lane, Marchington, UTTOXETER, Staffordshire	ST14 8XR	В	5	4	2	5
HMP/YOI EXETER	New North Road, EXETER, Devon	EX4 4EX	В	5	5	2	5
HMP GARTH	Ulnes Walton Lane, Leyland, PRESTON, Lancashire	PR26 8NE	В	4	4	1	5
HMP GARTREE	Gallow Field Road, MARKET HARBOROUGH, Leicestershire	LE16 7RP	В	5	3	1	5
HMP/YOI GLOUCESTER	Barrack Square, GLOUCESTER	GL1 2JN	В	5	5	2	5
HMP GRENDON	Edgcott, AYLESBURY, Bucks	HP18 OTL	В	4	3	1	4
HMP HOLME HOUSE	Holme House Road, STOCKTON-ON-TEES, Cleveland	TS18 2QU	В	5	5	2	5
HMP KINGSTON	122, Milton Road, PORTSMOUTH,Hampshire	PO3 6AS	В	5	5	2	5
HMP LEEDS	2, Gloucester Terrace, Armley, LEEDS, West Yorkshire	LS12 2TJ	В	5	5	2	5
HMP LEICESTER	Welford Road, LEICESTER	LE2 7AJ	В	5	5	2	5
HMP/YOI LEWES	1, Brighton Road, LEWES, East Sussex	BN7 1EA	В	5	5	2	5
HMP LIVERPOOL	68, Hornby Road, LIVERPOOL	L9 3DF	В	5	5	2	5
HMP LOWDHAM GRANGE	Lowdham, NOTTINGHAM, Nottinghamshire	NG14 7DA	В	4	4	1	5
HMP MAIDSTONE	36, County Road, MAIDSTONE, Kent	ME14 1UZ	В	5	5	2	5
HMP NOTTINGHAM	Perry Road, Sherwood, NOTTINGHAM	NG5 3AG	В	5	5	2	5
HMP/YOI PARC	Heol Hopcyn John, Coity, BRIDGEND, Mid- Glamorgan	CF35 6AR	В	5	3	2	5

HMP PARKHURST	Clissold Road, Parkhurst, NEWPORT, Isle of Wight	PO30 5NX	В	4	5	2	5
HMP PENTONVILLE	Caledonian Road, LONDON	N7 8TT	В	5	5	2	5
HMP PETERBOROUGH	Saville Road, Westwood, PETERBOROUGH, Cambridgeshire	PE3 7PD	В	5	5	2	5
HMP RYE HILL	Willoughby, RUGBY Warwickshire	CV23 8SZ	В	5	4	1	5
HMP SHREWSBURY	The Dana, SHREWSBURY, Shropshire	SY1 2HR	В	5	5	2	5
HMP SWALESIDE	Barbazon Road, Eastchurch, SHEERNESS, Isle of Sheppey, Kent	ME12 4AX	В	4	3	1	5
HMP SWANSEA	200, Oystermouth Road, SWANSEA, West Glamorgan	SA1 3SR	В	5	5	2	5
HMP WANDSWORTH	PO Box 757, Heathfield Road, Wandsworth LONDON	SW18 3HS	В	5	5	2	5
HMP WINCHESTER	Romsey Road, WINCHESTER, Hampshire	SO22 5DF	В	5	5	2	5
HMP WOLDS	Sands Lane, Everthorpe, BROUGH, East Yorkshire	HU15 2JZ	В	4	2	2	5
HMP WORMWOOD SCRUBS	PO Box 757, Du Cane Road, LONDON	W12 0AE	В	5	5	2	5
HSH ASHWORTH EAST	School Lane, Parkbourn, Maghull, LIVERPOOL	L31 1HW	В	5	5	2	5
MSU EDENFIELD Centre	Prestwich Hospital, Valley Park Road, off Bury New Rd (A56), Prestwich, MANCHESTER	M25 3BL	В	5	5	2	5
STC BRENTWOOD	Nr. St. Charles Road, off Weald Road, BRENTWOOD, Essex	CM14 4TP	В	5	5	2	5
STC GLYNNEATH	Nr. Derifach (B4242), Glynneath Business Park, Cwmgwrach, Glyn-Neath, Vale of Neath, NEATH, Neath & Port Talbot	SA11 5PY	В	3	4	2	5
STC HASSOCKFIELD	Corbridge Road, Medomsley, CONSETT, County Durham	DH8 6QY	В	5	5	1	5
STC MEDWAY	off Sir Evelyn Road, Chatham, ROCHESTER, Kent	ME1 3YB	В	5	5	2	5
STC OAKHILL	Tattenhoe Street, Woodhill, MILTON KEYNES, Bucks	MK5 6AH	В	4	4	1	5
STC RAINSBROOK	Willoughby, Nr. RUGBY, Warwickshire	CV23 8SY	В	5	4	1	5
HMP BARLINNIE	81, Lee Avenue, Barlinnie, GLASGOW	G33 2QX	В	5	5	2	5

HMP/YOI FOREST BANK	Agecroft Road, Pendlebury, MANCHESTER	M27 8FB	B C	5	5	2	5
MSU CANE HILL	Brighton Road, Coulsdon, CROYDON, Kent	CR5 3YL	ВC	4	5	2	5
MSU CHADWICK LODGE	Chadwick Drive, Eaglestone, MILTON KEYNES, Buckinghamshire	MK6 5LS	ВC	5	5	2	5
MSU COASTLANDS	Northgate Hospital,Great Yarmouth,Norfolk	NR30 1BU	ВC	5	4	2	5
MSU CROZIER TERRACE	1, Crozier Terrace, Hackney, LONDON	E9 6BE	B C	5	5	2	5
MSU GUILD LODGE	Guild Park, Whittingham Lane, Goosnargh, PRESTON Lancashire	PR3 2JH	ВC	4	3	1	5
MSU LANGDALE	Whittingham Hospital, Whittingham Lane, Goosnargh, PRESTON Lancashire	PR3 3JH	ВC	3	5	0	5
MSU RAVENSWOOD	Ravenswood House, Knowle Hospital, FAREHAM, Hampshire	PO17 5NA	ВC	4	4	1	5
MSU REASIDE Clinic	Reaside Drive, Birmingham Great Park, Bristol Road South, Rubery, BIRMINGHAM	B45 9BE	ВC	4	5	2	5
HMP CORNTON VALE	Cornton Road, STIRLING, Stirling	FK9 5NU	B C	5	5	2	5
MSU BLAIR UNIT	Royal Cornhill Hospital, Grampian University NHS Trust, Cornhill Road, ABERDEEN Aberdeenshire	AB9 2ZH	ВC	5	5	2	5
MSU PERTH	Murray Royal Hospital, Muirhall Road, Kinnoull, PERTH, Perthshire & Kinross	PH2 7BH	ВC	5	3	2	5
MSU ORCHARD CLINIC	Royal Edinburgh Hospital, 51, Morningside Place, Morningside, EDINBURGH	EH10 5HF	ВC	5	5	2	5
MSU PAISLEY	Dykebar Hospital Grahamston Road, Dykebar, PAISLEY, Renfrewshire	PA2 7DE	ВC	5	5	2	5
MSU STOBHILL	Stobhill NHS Trust Hospital, 133, Balornock Road, Springburn, GLASGOW	G21 3UW	ВC	5	5	2	5
RSU SHANNON CLINIC	Knockbracken Healthcare Park, Saintfield Road, BELFAST	BT8 8BH	ВC	4	5	2	5
HMP DORCHESTER	North Square, DORCHESTER, Dorset	DT1 1JD	BC	5	5	2	5

HMYOI LOW NEWTON	Finchale Avenue, Framwellgate Moor, Brasside, DURHAM	DH1 5SD	ВC	5	5	2	5
HMP/YOI NORWICH	Knox Road, Mousehold, NORWICH, Norfolk	NR1 4LU	B C	5	5	2	5
MCTC COLCHESTER	Berechurch Hall Road, COLCHESTER, Essex	CO2 9NU	ВC	4	4	1	4
HMP LOW MOSS	190, Crosshill Road, Bishopbriggs, GLASGOW	G64 2QB	B C	5	5	1	5
HMYOI POLMONT	Redding Road, Brightons, FALKIRK, Stirlingshire	FK2 0AB	ВC	5	4	2	5
HMP MAGILLIGAN	Point Road, Magilligan, LIMAVADY, Co.(London)derry	BT49 0LR	ВC	5	3	0	5
RS ST. MARY'S KENMURE	St. Mary's Road, Bishopbriggs, GLASGOW, East Dunbartonshire	G64 2EH	B C D	5	5	2	5
HMP CANTERBURY	46, Longport, CANTERBURY, Kent	CT1 1PJ	С	5	5	2	5
HMP/YOI CASTINGTON	Wansbeck Road, Acklington, Nr. Amble, MORPETH, Northumberland	NE65 9XG	С	4	3	1	4
HMYOI DEERBOLT	Bowes Road, BARNARD CASTLE, County Durham	DL12 9BG	С	4	5	2	5
HMYOI/RC FELTHAM	Bedfont Road, FELTHAM, Middlesex	TW13 4ND	С	5	4	2	5
HMYOI/RC GLEN PARVA	10, Tigers Road, Wigston, LEICESTER	LE18 4TN	С	5	5	2	5
HMP HINDLEY	Gibson Street, Bickershaw, WIGAN, Lancashire	WN2 5TH	С	5	5	2	5
HMP/YOI LANCASTER FARMS	Far Moor Lane, Stone Row Head,off Quernmore Road, LANCASTER,Lancashire	LA1 3QZ	С	5	4	1	5
HMYOI NORTHALLERTON	15a, East Road, NORTHALLERTON, North Yorkshire	DL6 1NW	С	5	5	2	5
HMYOI ONLEY	Willoughby, RUGBY, Warwickshire	CV23 8AP	С	5	4	1	5
HMYOI PORTLAND	Easton, PORTLAND, Dorset	DT5 1DF	С	5	4	2	5
HMYOI & RC READING	Forbury Road, READING, Berks	RG1 3HY	С	5	5	2	5
HMYOI STOKE HEATH	Stoke Heath, MARKET DRAYTON, Shropshire	TF9 2JL	С	3	2	2	5
HMYOI SWINFEN HALL	Swinfen, LICHFIELD, Staffs	WS14 9QS	С	5	5	1	5
HMYOI WETHERBY	York Road, WETHERBY, West Yorkshire	LS22 5ED	С	5	5	2	5
YTC GLENTHORNE	Kingsbury Road, Erdington, BIRMINGHAM	B24 9SA	С	5	5	2	5
YTC ST. CHARLES	Nr. St. Charles Road, off Weald Road, BRENTWOOD, Essex	CM14 4TP	С	5	5	2	5

STOKE HOUSE	Lloyd Crescent, Wyken, COVENTRY	CV2 5NY	С	5	5	2	5
HMP BELFAST	Landscape Terrace, Crumlin Road (A52), BELFAST	BT14 6AD	С	5	5	2	5
HMP & YOC HYDEBANK WOOD	Hospital Road, Hydebank Wood, BELFAST	BT8 8NA	С	5	5	2	5
IDU CRUMLIN ROAD	Landscape Terrace, Crumlin Road (A52), BELFAST	BT14 6AD	С	5	5	2	5
JJC ST. PATRICK'S	Glen Road (A55), West Belfast, BELFAST, Co.Antrim	BT11 8BX	С	5	5	2	5
JJC RATHGAEL	School Avenue, Newtownards Road (A21), BANGOR, Co.Down	BT19 1TA	С	5	4	2	5
SARK ISLAND PRISON	Mill Lane, La Collinette, Sark, GUERNSEY	GY9 0SA	С	5	5	2	5
HMP ACKLINGTON	Wansbeck Road, Acklington, Nr. Amble, MORPETH, Northumberland	NE65 9XF	С	4	3	0	4
HMP ASHWELL	OAKHAM, Rutland	LE15 7LF	С	4	4	1	5
HMYOI BRINSFORD	New Road, Featherstone, WOLVERHAMPTON, Staffs	WV10 7PY	С	5	5	2	5
HMP BROCKHILL	Hewell Grange, REDDITCH, Worcestershire	B97 6RD	С	5	4	2	5
HMP BUCKLEY HALL	Buckley Farm Lane, ROCHDALE, Lancashire	OL12 9DP	С	5	5	2	5
HMP CAMP HILL	High Road, Parkhurst, NEWPORT, Isle of Wight	PO30 5PB	С	4	5	1	5
HMP CHANNINGS WOOD	Denbury, NEWTON ABBOT, Devon	TQ12 6DW	С	3	3	1	5
HMP COLDINGLEY	Shaftesbury Road, Bisley, WOKING, Surrey	GU24 9EX	С	4	5	2	5
HMP DARTMOOR	Princetown, YELVERTON, Devon	PL20 6RR	С	5	3	1	5
HMP ELMLEY	Church Road, Eastchurch, SHEERNESS, Isle of Sheppey, Kent	ME12 4DZ	С	4	3	1	5
HMP ERLESTOKE	DEVIZES, Wiltshire	SN10 5TU	С	4	3	0	4
HMP EVERTHORPE	BROUGH, East Yorkshire	HU15 1RB	С	4	2	2	5
HMP FEATHERSTONE	New Road, WOLVERHAMPTON, Staffs	WV10 7PU	С	5	5	2	5
HMP/YOI GUYS MARSH	SHAFTESBURY, Dorset	SP7 0AH	С	4	2	1	5
HMP HAVERIGG	MILLOM, Cumbria	LA18 4NA	С	5	3	1	5
HMP HIGHPOINT	Stradishall, NEWMARKET, Suffolk	CB8 9YG	С	5	2	2	3

HMYOI HUNTERCOMBE	Huntercombe Place, Nuffield, HENLEY-ON-THAMES, Oxfordshire	RG9 5SB	С	3	5	0	4
HMP LANCASTER CASTLE	The Castle, LANCASTER, Lancashire	LA1 1YL	С	5	5	2	5
HMP LINCOLN	Greetwell Road, LINCOLN	LN2 4BD	С	5	5	2	5
HMP LINDHOLME	Bawtry Road, Hatfield Woodhouse,DONCASTER	DN7 6EE	С	4	4	2	5
HMP LITTLEHEY	Crow Spinney Lane, West Perry, HUNTINGDON, Cambridgeshire	PE28 0SR	С	5	3	1	5
HMP/YOI MOORLAND CLOSED	Bawtry Road, Nr. Hatfield Woodhouse, DONCASTER, South Yorkshire	DN7 6BW	С	4	4	2	5
HMP THE MOUNT	Molyneaux Avenue, Bovingdon, HEMEL HEMPSTEAD, Herts	HP3 ONZ	С	5	5	2	5
HMP RANBY	A620 Straight Mile Road, Nr. Ranby, RETFORD, Nottinghamshire	DN22 8EU	С	4	5	0	5
HMP RISLEY	617, Warrington Road, Risley, WARRINGTON, Cheshire	WA3 6BP	С	5	5	2	5
HMP SEND	Ripley Road, Send, WOKING, Surrey	GU23 7LJ	С	4	4	2	5
HMP SHEPTON MALLET	Cornhill, SHEPTON MALLET, Somerset	BA4 5LU	С	5	5	2	5
HMP STAFFORD	54, Gaol Road, STAFFORD	ST16 3AW	С	5	5	2	5
HMP STOCKEN	Stocken Hall Road, Stretton, OAKHAM, Rutland	LE15 7RD	С	4	4	1	5
HMP THE VERNE	The Verne, PORTLAND, Dorset	DT5 1EQ	С	4	5	2	5
HMYOI WARREN HILL	Rectory Road, Hollesley, WOODBRIDGE, Suffolk	IP12 3JW	С	5	5	2	5
HMP WAYLAND	Griston, THETFORD, Norfolk	IP25 6RL	С	5	4	1	5
HMP THE WEARE	Portland Dock, Rotherham Road, Fortuneswell, PORTLAND, Dorset	DT5 1PZ	С	4	3	1	4
HMP WELLINGBOROUG H	Millers Park, Doddington Road, WELLINGBOROUGH, Northants	NN8 2NH	С	5	5	2	5
HMP WHATTON	14, Cromwell Road, NOTTINGHAM	NG13 9FQ	С	5	3	1	5
HMP WYMOTT	Ulnes Walton Lane, Leyland, PRESTON	PR26 8LW	С	4	4	2	5
IRC DOVER	The Citadel, Western Heights, DOVER, Kent	CT17 9DR	С	5	5	1	5
IRC HASLAR	2, Dolphin Way, GOSPORT, Hampshire	PO12 2AW	С	5	5	2	5

HMYOI COLCHESTER	Berechurch Hall Road, COLCHESTER, Essex	CO2 9NU	С	4	4	1	4
MSU DENIS HILL	Bethlem Royal Hospital, Orchard Road, Beckenham, KENT	BR3 3BX	С	5	5	2	5
MSU FROMESIDE	Blackberry Hill Hospital, Manor Road, Fishponds, BRISTOL	BS16 2EW	С	5	5	2	5
RSU SCOTT CLINIC	Rainhill Road, ST. HELENS, Merseyside	WA9 5BD	С	5	5	2	5
MSU WALLINGFORD Clinic	Fair Mile Hospital, Reading Road, Cholsey, WALLINGFORD, Oxfordshire	OX10 9HH	С	5	5	2	5
LASCH ALDINE HOUSE	75, Limb Lane, Dore, SHEFFIELD	S17 3ES	С	5	5	2	5
LASCH ATKINSON UNIT	Atkinson Close, Beacon Lane, EXETER, Devon	EX4 8NA	С	5	4	2	5
LASCH AYCLIFFE	Copelaw, NEWTON AYCLIFFE, County Durham	DL5 6JB	С	5	3	2	5
LASCH BARTON MOSS	Barton Moss Road, Chat Moss, Eccles, MANCHESTER	M30 7RL	С	5	5	2	5
LASCH BEECHFIELD	Effingham Road, Copthorne, CRAWLEY, West Sussex	RH10 3HZ	С	5	4	2	5
LASCH BRIARS HAY	Mill Lane, Rainhill, ST. HELENS, Merseyside	L35 6NE	С	5	5	2	5
LASCH BRUNEL UNIT	125c, Market Street, Clay Cross, CHESTERFIELD, Derbyshire	S45 9LX	С	5	5	2	5
LASCH CLARE LODGE	104, Welmore Road, Glinton,PETERBOROUGH, Cambridgeshire	PE6 7LU	С	4	4	1	5
LASCH CLAYFIELDS HOUSE	18-20, Moorbridge Lane, Stapleford, NOTTINGHAM	NG9 8GU	С	5	5	2	5
LASCH DALES HOUSE	Normoss Road, Flyde Community, BLACKPOOL Lancashire	FY3 0BE	С	5	4	2	5
LASCH EARLSWOOD	18, Gravelly Hill North, Erdington, BIRMINGHAM, West Midlands	B23 6BQ	С	5	5	2	5
LASCH EAST MOOR	East Moor Lane, Adel, LEEDS, West Yorkshire	LS16 8EB	С	4	5	1	5
LASCH GLADSTONE HOUSE	Dyson Hall Campus, Higher Lane, Fazakerly, LIVERPOOL	L9 7HB	С	5	5	2	5
LASCH HILLSIDE	off Burnside, Cimla, NEATH, Neath & Port Talbot	SA11 1UL	С	5	5	1	5

LASCH KYLOE HOUSE	Netherton Park, Stannington, MORPETH, Northumberland	NE61 6DE	С	5	3	2	5
LASCH LANSDOWNE	Hawks Town Close, Hawks Road, Magham, HAILSHAM, East Sussex	BN27 1HT	С	4	4	2	5
LASCH LEVERTON HALL	Dark Lane, Nr. Great Warley, BRENTWOOD, Essex	CM14 5LL	С	5	5	2	5
LASCH LINCOLNSHIRE	Rookery Avenue, SLEAFORD, Lincolnshire	NG34 7TY	С	5	4	1	5
LASCH RED BANK	Winwick Road, NEWTON-LE-WILLOWS, Merseyside	WA12 8EA	С	5	5	2	5
LASCH REDSANDS	Oak House, 251, Crewe Road, Willaston, NANTWICH, Cheshire	CW5 6NE	С	4	5	2	5
LASCH ST. JOHN'S	St. John's Road, Tiffield, TOWCESTER, Northamptonshire	NN12 8AA	С	5	2	2	5
LASCH STAMFORD HOUSE	206, Goldhawk Road, Sheppards Bush, LONDON	W12 9PA	С	5	5	2	5
LASCH SUTTON PLACE	347, Saltshouse Road, HULL, North Humberside	HU8 9HR	С	5	5	2	5
LASCH SWANWICK LODGE	Glen Road, off Swanwick Lane, Lower Swanwick, SOUTHAMPTON, Hampshire	SO31 7HD	С	5	5	2	5
LASCH THORNBURY HOUSE	40, The Moors, KIDLINGTON, Oxon	OX5 2AL	С	5	4	2	5
LASCH VINNEY GREEN	Emersons Green Lane, Mangotsfield, Nr. BRISTOL, South Gloucestershire	BS16 7AA	С	5	5	2	5
LASCH WATLING HOUSE	Watling Street, Gailey, STAFFORD, Staffordshire	ST19 5PR	С	5	5	2	5
HMP CRAIGINCHES	4, Grampian Place, Craiginches, ABERDEEN Aberdeenshire	AB11 8FN	С	5	5	1	5
HMP DUMFRIES	Terregles Street, DUMFRIES, Dumfries & Galloway	DG2 9AX	С	5	5	1	5
HMP EDINBURGH	33, Stenhouse Road, EDINBURGH	EH11 3LN	С	5	5	2	5
HMP GREENOCK	85, Old Inverkip Road, Gateside, GREENOCK, Inverclyde	PA16 9AJ	С	5	5	2	5
HMP KERR HOUSE	HMP Shotts Newmill & Canthill Road, SHOTTS, North Lanarkshire	ML7 4LE	С	3	4	1	4
HMP FOYLEVIEW	HMP MAGILLIGAN, Point Road, Magilligan, LIMAVADY, Co.(London)derry	BT49 0LR	С	5	3	0	5

JJC LISNEVIN	2, Drumfad Road,Millisle,NEWTOWNA RDS,Co.Down	BT22 2JQ	С	5	3	0	5
JJC NORTHERN IRELAND	School Avenue, Newtownards Road (A21), BANGOR, Co.Down	BT19 1TA	С	5	4	2	5
HMP PORTERFIELD	Duffy Drive, INVERNESS, Highland	IV2 3HH	C ~D	5	5	2	5
LAH HOWDENHALL	Braid Unit, 39, Howdenhall Road, EDINBURGH	EH16 6TY	C ~D	5	5	2	5
RS KIBBLE	Goudie Street, PAISLEY, Renfrewshire	PA3 2LG	C ~D	5	5	2	5
RS OAKBANK	Midstocket Road, ABERDEEN, Aberdeenshire	AB15 5XP	C ~D	5	4	2	5
LAH ST. KATHERINE'S	Guthrie Unit, 29b, Balmwell Terrace EDINBURGH	EH16 6PS	C ~D	5	5	2	5
HMP BLANTYRE HOUSE	Goudhurst, CRANBROOK, Kent	TN17 2NH	C D	3	5	1	5
HMP/YOI DRAKE HALL	Patterson Avenue, Sturbridge, Nr. Eccleshall, STAFFORD, Staffordshire	ST21 6LQ	C D	4	5	2	5
HMP MORTON HALL	Swinderby, LINCOLN	LN6 9PT	C D	4	4	1	5
HMP ROCHESTER	1 Fort Road, ROCHESTER, Kent	ME1 3QS	C D	5	5	2	5
RS LINN MOOR	Nr. PETERCULTER, Aberdeen, Aberdeenshire	AB14 0PJ	C D	5	4	1	4
HMP LATCHMERE HOUSE	Church Road, Ham Common, RICHMOND, Surrey	TW10 5HH	C D	5	4	1	5
HMP USK	47, Maryport Street, USK, Gwent	NP15 1XP	C D	4	5	2	5
HMP WEALSTUN	WETHERBY, West Yorkshire	LS23 7AZ	C D	4	5	1	5
LASCH ORCHARD LODGE	within grounds of Orchard School, William Booth Road, Anerley, LONDON	SE20 8BG	C D	5	5	2	5
LASCH ST. CATHERINE'S	off Blackbrook Road, Blackbrook, ST. HELENS, Merseyside	WA11 9RJ	C D	5	5	2	5
LAH THE ELMS	Elm Court, 317, South Road, Lochee, DUNDEE, Angus	DD2 2RT	C D	5	5	2	5
RS GOOD SHEPHERD	Greenock Road, BISHOPTON, Renfrewshire	PA7 5PF	C D	5	5	2	5
RS KERELAW	Kerelaw Campus, Kerelaw Road, STEVENSTON, North Ayrshire	KA20 4JY	C D	4	5	2	5
RS ROSSIE Secure Accommodation Services	Westerton, Nr. MONTROSE, Angus	DD10 9TW	C D	5	4	1	5

RS ST. PHILIP'S	Beechwood House, Plains, by AIRDRIE, North Lanarkshire	ML6 7SF	C D	4	5	2	5
RS SPRINGBOIG ST. JOHN'S	1190, Edinburgh Road, Shettleston, GLASGOW	G33 4EH	C D	5	5	2	5
HMP/YOI ASKHAM GRANGE	Askham Richard, YORK	YO23 3FT	D	5	4	2	4
HMP/YOI EAST SUTTON PARK	Sutton Valence, MAIDSTONE, Kent	ME17 3DF	D	3	4	1	5
HMP FORD	ARUNDEL, West Sussex	BN18 0BX	D	5	5	1	5
HMP HEWELL GRANGE	REDDITCH, Worcs	B97 6QQ	D	4	3	2	5
HMP KIRKHAM	Freckleton Road, PRESTON, Lancashire	PR4 2RN	D	5	5	2	5
HMP LEYHILL	Cromhall, WOTTON- UNDER-EDGE, Gloucestershire	GL12 8BT	D	4	5	1	4
HMP/YOI MOORLAND OPEN	Thorne Road, Hatfield, DONCASTER, South Yorkshire	DN7 6EL	D	5	5	2	5
HMP NORTH SEA CAMP	Croppers Lane, Freiston, BOSTON, Lincolnshire	PE22 0QX	D	3	1	0	4
HMP SPRING HILL	Edgcott, AYLESBURY, Bucks	HP18 0TH	D	4	3	1	4
HMP STANDFORD HILL	Church Road, Eastchurch,SHEERNESS, Isle of Sheppey,Kent	ME12 4AA	D	4	3	1	4
HMP SUDBURY	Sudbury, ASHBOURNE, Derbyshire	DE6 5HW	D	5	5	2	5
HMYOI THORN CROSS	Arley Road, Appleton Thorn, WARRINGTON, Cheshire	WA4 4RL	D	5	5	2	5
HMP CASTLE HUNTLY	Longforgan, DUNDEE, Angus	DD2 5HL	D	5	2	2	5
HMP NORANSIDE	Fern, FORFAR, Angus	DD8 3QY	D	3	2	1	4
HMP WAKEFIELD	5 Love Lane, WAKEFIELD, West Yorkshire	WF2 9AG	МА	5	5	2	4
HMP HIGH DOWN	Highdown Lane, off Sutton Lane, Belmont, SUTTON, Surrey/London	SM2 5PJ	МА	5	4	2	5
HSH ASHWORTH NORTH	School Lane, Parkbourn, Maghull, LIVERPOOL	L31 1HW	M A	5	5	2	5
HMP BELMARSH	Western Way, Thamesmead, LONDON	SE28 0EB	M A	5	4	2	5
HMP FRANKLAND	Brasside, DURHAM	DH1 5YD	M A	5	4	2	5
HMP WOODHILL	Tattenhoe Street, Woodhill, MILTON KEYNES, Bucks	MK4 4DA	M A	3	4	1	5
HMP SHOTTS	Newmill & Canthill Road, SHOTTS, North Lanarkshire	ML7 4LE	M A	3	4	1	4
HMP WHITEMOOR	Longhill Road, MARCH, Cambs	PE15 0PR	MAB	4	5	1	5
HMP HULL	Hedon Road, HULL, North Humberside	HU9 5LS	M A B	5	5	2	5

HSH RAMPTON HOSPITAL	Flemming Drive, Woodbeck, RETFORD, Nottinghamshire	DN22 0PD	M A B	4	5	1	4
HSH THE STATE HOSPITAL	110, Lampits Road, Carstairs Junction, Nr. Carstairs, LANARK, South Lanarkshire	ML11 8RP	M A B	4	2	2	5
HMP DURHAM	19b, Old Elvet, DURHAM	DH1 3HU	M A B	5	5	2	4
HMP FULL SUTTON	Full Sutton, YORK	YO41 1PS	M A B	4	3	1	5
HMP LONG LARTIN	South Littleton, EVESHAM, Worcestershire	WR11 8TZ	M B	4	3	2	4
HMP/YOI ASHFIELD	Shortwood Road, Pucklechurch, BRISTOL	BS16 9QJ		5	5	2	5
HMYOI BULLWOOD HALL	High Road, HOCKLEY, Essex	SS5 4TE		4	5	2	5
HMP COOKHAM WOOD	Sir Evelyn Road, Chatham, ROCHESTER, Kent	ME1 3LU		5	5	2	5
HMP DOWNVIEW	Highdown Lane, off Sutton Lane, Belmont, SUTTON, Surrey/London	SM2 5PD		5	5	2	5
HMP/YOI EASTWOOD PARK	Falfield, WOTTON- UNDER-EDGE, Gloucestershire	GL12 8DB		5	3	2	5
HMP FOSTON HALL	Foston, DERBY, Derbyshire	DE65 5DN		5	3	2	5
HMP/YOI HOLLOWAY	Parkhurst Road, LONDON	N7 0NU		5	5	2	5
HMP/YOI NEW HALL	Dial Wood, Flockton, WAKEFIELD, West Yorkshire	WF4 4AX		5	5	2	5
HMP/YOI PRESCOED	47, Maryport Street, USK, Gwent	NP15 1XP		4	5	2	4
HMP/YOI STYAL	Styal, WILMSLOW, Cheshire	SK9 4HR		5	5	2	5
HMU PETERHEAD	PETERHEAD, Aberdeenshire	AB42 2YY		5	4	1	5
HMU SHOTTS	HMP Shotts Newmill & Canthill Road, SHOTTS, North Lanarkshire	ML7 4LE		3	4	1	4
IDC DUNGAVEL	STRATHAVEN, South Lanarkshire	ML10 6RF		4	5	1	5

# **APPENDIX II: PRISON CELL WITH FSS ON**

## THE WINDOW



## **APPENDIX III: BB857 DIODE DATA SHEET**

Electrical Characteristics at T <sub>A</sub> = 25°C, unless otherwise specified									
Parameter	Symbol		Values		Unit				
		min.	typ.	max.					
DC Characteristics	-	-							
Reverse current	I <sub>R</sub>				nA				
$V_{R}$ = 30 $\vee$		-	-	10					
V <sub>R</sub> = 30 ∨, <i>T</i> <sub>A</sub> = 85 °C		-	-	200					
AC Characteristics									
Diode capacitance	CT				pF				
$V_{R} = 1 \lor, f = 1 MHz$		6	6.6	7.2					
V <sub>R</sub> = 25 ∨, <i>f</i> = 1 MHz		0.5	0.55	0.65					
<i>V</i> <sub>R</sub> = 28 ∨, <i>f</i> = 1 MHz		0.45	0.52	-					
Capacitance ratio	C <sub>T1</sub> /C <sub>T25</sub>	10.2	12	-	-				
$V_{\rm R}$ = 1 V, $V_{\rm R}$ = 25 V, $f$ = 1 MHz									
Capacitance ratio	C <sub>T1</sub> /C <sub>T28</sub>	9.7	12.7	-					
$V_{\rm R}$ = 1 V, $V_{\rm R}$ = 28 V, $f$ = 1 MHz									
Capacitance matching <sup>1)</sup>	$\Delta C_{T}/C_{T}$	-	-	5	%				
$V_{\rm R}$ = 1V 28V, <i>f</i> = 1 MHz, 7 diodes sequence									
Series resistance	rs	-	1.5	-	Ω				
V <sub>R</sub> = 5 ∨, <i>f</i> = 470 MHz									
Series inductance	LS	-	0.6	-	nH				



## **APPENDIX IV: BB131 DIODE DATA SHEET**

#### VHF variable capacitance diode

BB131

#### CHARACTERISTICS

T<sub>j</sub> = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I <sub>R</sub>	reverse current	V <sub>R</sub> = 30 V; see Fig.3	-	10	nA
		V <sub>R</sub> = 30 V; T <sub>j</sub> = 85 °C; see Fig.3	-	200	nA
r <sub>s</sub>	diode series resistance	f = 470 MHz; note 1	-	3	Ω
C <sub>d</sub>	diode capacitance	$V_R$ = 0.5 V; f = 1 MHz; see Figs 2 and 4	8	17	pF
		$V_R$ = 28 V; f = 1 MHz; see Figs 2 and 4	0.7	1.055	pF
C	capacitance ratio	f = 1 MHz	12	16	
℃d(28V)					[

#### Note

1.  $V_R$  is the value at which  $C_d$  = 9 pF.



T<sub>j</sub> = 25 °C; f = 1 MHz.

Diode capacitance as a function of reverse voltage; typical values.